

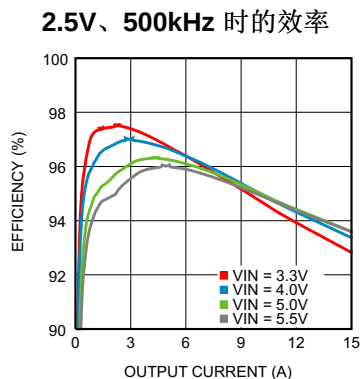
具有频率同步功能的 LM21215A 2.95V 至 5.5V、15A、电压模式同步降压转换器

1 特性

- 高效同步直流/直流转换器
 - 输入电压范围为 2.95V 至 5.5V
 - 可调输出电压范围为 0.6V 至 V_{IN}
 - 输出电流高达 15A
- 频率同步为 300kHz 至 1.5MHz
- 集成 7mΩ PMOS 降压开关支持 100% 占空比，适用于低压降压
- 集成 4.3mΩ NMOS 同步整流器省去了肖特基二极管
- 精确 $\pm 1\%$ 内部电压基准
- 自动二极管仿真模式可提高轻载时的效率
- 单调预偏置启动
- 内部 0.5ms 或外部可调软启动
- 输出电压跟踪功能
- 超快线路和负载瞬态响应
 - 电压模式 PWM 控制
 - 高带宽电压环路误差放大器
- 具有迟滞功能的精密使能端
- 集成 OVP、UVP、OCP 和 UVLO
- 开漏电源正常指示器
- 具有迟滞功能的热关断保护
- 热增强型 HTSSOP-20 封装
- 使用 LM21215A 并借助 **WEBENCH®** 电源设计器创建定制设计方案

2 应用

- 电信基础设施
- DSP 和 FPGA 内核电压电源
- 高效 POL 转换
- 嵌入式计算、服务器和存储



3 说明

LM21215A 是一款同步降压直流/直流转换器，可在输出电压低至 0.6V 时提供高达 15A 的输出电流。

LM21215A 在 2.95V 至 5.5V 的输入电压范围内以超高效率工作，适合各种低电压系统。该电压模式控制环路具有高增益带宽误差放大器，可提供高噪声抗扰度、低占空比能力，并且可通过任何类型的输出电容器轻松进行稳定工作补偿，从而提供最大的灵活度和易用性。

LM21215A 具有内部过压保护 (OVP) 和逐周期过流保护 (OCP)，可提高系统可靠性。精密使能引脚和集成 UVLO 支持对器件的打开进行严格的控制和定序。启动浪涌电流受内部固定或外部可调的软启动电路限制。集成开漏 PGOOD 指示器可提供故障报告和电源定序。

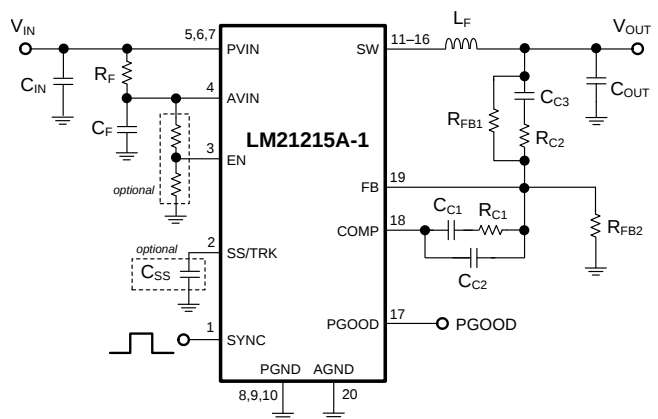
其他功能包括辅助电压轨跟踪、单调启动至预偏置负载和将开关频率同步至 300kHz 和 1.5MHz 范围内的外部时钟信号，适用于拍频敏感型和多稳压器应用。LM21215A 采用热增强型 20 引脚 HTSSOP 封装，该封装的外露焊盘焊接至 PCB 以获得极低的结至板热阻。

器件信息(1)

器件型号	封装	封装尺寸 (标称值)
LM21215A	HTSSOP (20)	6.50mm × 4.40mm

(1) 如需了解所有可用封装，请参阅产品说明书末尾的可订购产品附录。

典型应用电路



目录

1	特性	1	7.4	Device Functional Modes	15
2	应用	1	8	Application and Implementation	17
3	说明	1	8.1	Application Information	17
4	修订历史记录	2	8.2	Typical Applications	17
5	Pin Configuration and Functions	3	9	Power Supply Recommendations	28
6	Specifications	4	10	Layout	29
6.1	Absolute Maximum Ratings	4	10.1	Layout Guidelines	29
6.2	ESD Ratings	4	10.2	Layout Example	31
6.3	Recommended Operating Conditions	4	11	器件和文档支持	32
6.4	Thermal Information	4	11.1	器件支持	32
6.5	Electrical Characteristics	5	11.2	文档支持	32
6.6	Typical Characteristics	7	11.3	社区资源	33
7	Detailed Description	11	11.4	商标	33
7.1	Overview	11	11.5	静电放电警告	33
7.2	Functional Block Diagram	11	11.6	Glossary	33
7.3	Feature Description	12	12	机械、封装和可订购信息	33

4 修订历史记录

注：之前版本的页码可能与当前版本有所不同。

Changes from Revision C (January 2016) to Revision D Page

- 仅有编辑更改，无技术性修订；添加了 WEBENCH 链接 1

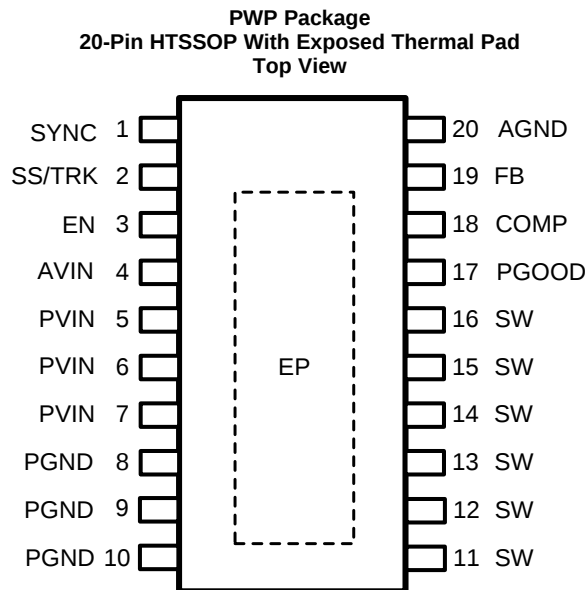
Changes from Revision B (March 2013) to Revision C Page

- 添加了 ESD 额定值表、特性说明部分、器件功能模式、应用和实施部分、电源建议部分、布局部分、器件和文档支持部分以及机械、封装和可订购信息部分 1

Changes from Revision A (March 2013) to Revision B Page

- Changed layout of National Data Sheet to TI format 27

5 Pin Configuration and Functions



Pin Functions

PIN		TYPE ⁽¹⁾	DESCRIPTION
NO.	NAME		
1	SYNC	I	Frequency synchronization input pin. Applying a clock signal to this pin forces the device to switch at the clock frequency. If left unconnected, the frequency defaults to 500 kHz.
2	SS/TRK	I	Soft-start control pin. An internal 2-μA current source charges an external capacitor connected between this pin and AGND to set the output voltage ramp rate during startup. This pin can also be used to configure the tracking feature.
3	EN	I	Active high precision enable input. If not used, the EN pin can be left open, which will go high due to an internal pullup current source.
4	AVIN	P	Analog input voltage supply that generates the internal bias. Connect PVIN to AVIN through a low pass RC filter to minimize the influence of input rail ripple and noise on the analog control circuitry.
5–7	PVIN	P	Input voltage to the power switches inside the device. Connect these pins together at the device. Locate a low ESR input capacitance as close as possible to these pins.
8–10	PGND	G	Power ground pins for the internal power switches.
11–16	SW	P	Switch node pins. Tie these pins together locally and connect to the filter inductor.
17	PGOOD	O	Open-drain power good indicator.
18	COMP	O	Compensation pin is connected to the output of the voltage loop error amplifier.
19	FB	I	Feedback pin is connected to the inverting input of the voltage loop error amplifier.
20	AGND	G	Quiet analog ground for the internal reference and bias circuitry.
EP	Exposed Pad	P	Exposed metal pad on the underside of the package with an electrical and thermal connection to PGND. Connect this pad to the PC board ground plane to improve thermal dissipation.

(1) P = Power, G = Ground, I = Input, O = Output.

6 Specifications

6.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted)⁽¹⁾⁽²⁾

	MIN	MAX	UNIT
PVIN ⁽³⁾ to GND, AVIN to GND	−0.3	6	V
SW ⁽⁴⁾ to GND	−0.3	V _{PVIN} + 0.3	V
EN, FB, COMP, PGOOD, SS/TRK to GND	−0.3	V _{PVIN} + 0.3	V
Storage temperature, T _{stg}	−65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.
- (3) The PVIN pin can tolerate transient voltages up to 6.5 V for a duration of up to 6 ns. These transients can occur during normal operation of the device.
- (4) The SW pin can tolerate transient voltages up to 9 V for a duration of 6 ns and −1 V for a duration of 4 ns. These transients can occur during normal operation of the device.

6.2 ESD Ratings

		VALUE	UNIT
V _(ESD) Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±500	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
Input voltages	PVIN, AVIN to GND	2.95	5.5	V
Output current, I _{OUT}		−0.3	15	A
Junction temperature, T _j		−40	125	°C

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		LM21215A	UNIT
		PWP (HTSSOP)	
		20 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	30.5	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	12.9	°C/W
R _{θJB}	Junction-to-board thermal resistance	0.3	°C/W
ψ _{JT}	Junction-to-top characterization parameter	0.3	°C/W
ψ _{JB}	Junction-to-board characterization parameter	2.3	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	0	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics

Unless otherwise stated, the following conditions apply: $V_{PVIN} = V_{AVIN} = 5\text{ V}$, $T_J = 25^\circ\text{C}$. Minimum and maximum limits are specified through test, design, or statistical correlation. Typical values represent the most likely parametric norm at $T_J = 25^\circ\text{C}$ and are provided for reference purposes only.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
SYSTEM							
V _{FB}	Feedback voltage	V _{IN} = 2.95 V to 5.5 V	T _J = −40°C to 125°C T _J = 25°C	−1%		1%	V
ΔV _{OUT} /ΔI _{OUT}	Load regulation				0.02%		V _{OUT} /A
ΔV _{OUT} /ΔV _{IN}	Line regulation				0.1%		V _{OUT} /V
R _{DS(on)-HS}	High-side switch on-resistance	I _{SW} = 12 A	T _J = −40°C to 125°C T _J = 25°C			9 7	mΩ
R _{DS(on)-LS}	Low-side switch on-resistance	I _{SW} = 12 A	T _J = −40°C to 125°C T _J = 25°C			6 4.3	mΩ
I _{CLR}	HS rising switch current limit	T _J = −40°C to 125°C T _J = 25°C		17.3		22.8	A
I _{CLF}	LS falling switch current limit				14		A
V _{ZX}	Zero-cross voltage			−8	3	12	mV
I _Q	Operating quiescent current	T _J = −40°C to 125°C T _J = 25°C				3 1.5	mA
I _{SD}	Shutdown quiescent current	V _{EN} = 0 V	T _J = −40°C to 125°C T _J = 25°C			70 50	μA
V _{UVLO}	AVIN undervoltage lockout	AVIN rising	T _J = −40°C to 125°C T _J = 25°C	2.45		2.95 2.70	V
V _{UVLOHYS}	AVIN undervoltage lockout hysteresis	T _J = −40°C to 125°C T _J = 25°C		140		280 200	mV
V _{TRACKOS}	SS/TRACK accuracy (V _{SS/TRK} − V _{FB})	0 < V _{SS/TRK} < 0.55 V	T _J = −40°C to 125°C T _J = 25°C	−10		20 6	mV
I _{SS}	Soft-start pin source current	T _J = −40°C to 125°C T _J = 25°C		1.3		2.5 1.9	μA
t _{INTSS}	Internal soft-start ramp to V _{ref}	SS/TRK open	T _J = −40°C to 125°C T _J = 25°C	350		675 500	μs
t _{RESETSS}	Device reset to soft-start ramp	T _J = −40°C to 125°C T _J = 25°C		50		200 110	μs
OSCILLATOR							
f _{SYNCR}	SYNC frequency range	T _J = −40°C to 125°C		300		1500	kHz
f _{DEFAULT}	Default (no SYNC signal) frequency	T _J = −40°C to 125°C T _J = 25°C		475		525 500	kHz
t _{SY_SW}	Time from V _{SYNC} falling to V _{SW} rising				200		ns
t _{SY_MIN}	Minimum SYNC pulse width, high or low				100		ns
t _{HSBLANK}	HS OCP blanking time	Rising edge of SW to I _{CLR} comparison			55		ns
t _{LSBLANK}	LS OCP blanking time	Falling edge of SW to I _{CLF} comparison			400		ns
t _{ZXBLANK}	Zero cross blanking time	Falling edge of SW to V _{ZX} comparison			120		ns
t _{MINON}	Minimum HS on-time				140		ns
ΔV _{RAMP}	PWM ramp peak-peak voltage				0.8		V
ERROR AMPLIFIER							
V _{OL}	Error amplifier open-loop gain	I _{COMP} = −65 μA to 1 mA			95		dB
GBW	Error amplifier gain-bandwidth				11		MHz
I _{FB}	Feedback pin bias current	V _{FB} = 0.6 V			1		nA

Electrical Characteristics (continued)

Unless otherwise stated, the following conditions apply: $V_{PVIN} = V_{AVIN} = 5\text{ V}$, $T_J = 25^\circ\text{C}$. Minimum and maximum limits are specified through test, design, or statistical correlation. Typical values represent the most likely parametric norm at $T_J = 25^\circ\text{C}$ and are provided for reference purposes only.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
I _{COMPSRC}	COMP output source current			1			mA
I _{COMPSINK}	COMP output sink current			65			μA
POWER GOOD							
V _{OVP}	Overvoltage protection rising threshold	V _{FB} rising	T _J = −40°C to 125°C	105%	120%		V _{FB}
			T _J = 25°C	112.5%			
V _{OVPHYS}	Overvoltage protection hysteresis	V _{FB} falling		2%			V _{FB}
V _{UVP}	Undervoltage protection rising threshold	V _{FB} rising	T _J = −40°C to 125°C	82%	97%		V _{FB}
			T _J = 25°C	90%			
V _{UVPHYS}	Undervoltage protection hysteresis	V _{FB} falling		2.5%			V _{FB}
t _{PGDGL}	PGOOD deglitch low	Time to PGOOD falling after OVP/UVP event		15			μs
t _{PGDGH}	PGOOD deglitch high	Minimum low pulse		12			μs
R _{PGOOD}	PGOOD pulldown resistance	T _J = −40°C to 125°C		10	40		Ω
		T _J = 25°C		20			
I _{PGOODLEAK}	PGOOD leakage current	V _{PGOOD} = 5 V		1			nA
LOGIC							
V _{IHSYNC}	SYNC pin logic high			2			V
V _{ILSYNC}	SYNC pin logic low					0.8	V
V _{IHENR}	EN pin rising threshold	V _{EN} Rising	T _J = −40°C to 125°C	1.2	1.45		V
			T _J = 25°C	1.35			
V _{ENHYS}	EN pin hysteresis	T _J = −40°C to 125°C		50	180		mV
		T _J = 25°C		110			
I _{EN}	EN pin pullup current	V _{EN} = 0 V		2			μA
THERMAL SHUTDOWN							
T _{TSD}	Thermal shutdown			165			°C
T _{TSD-HYS}	Thermal shutdown hysteresis			10			°C

6.6 Typical Characteristics

Unless otherwise specified: $V_{IN} = 5\text{ V}$, $V_{OUT} = 1.2\text{ V}$, $L_F = 0.56\text{ }\mu\text{H}$ ($1.8\text{ m}\Omega\text{ }R_{DCR}$), $C_{SS} = 33\text{ nF}$, $f_{SW} = 500\text{ kHz}$, $T_A = 25^\circ\text{C}$ for efficiency curves, loop gain plots and waveforms, and $T_J = 25^\circ\text{C}$ for all others.

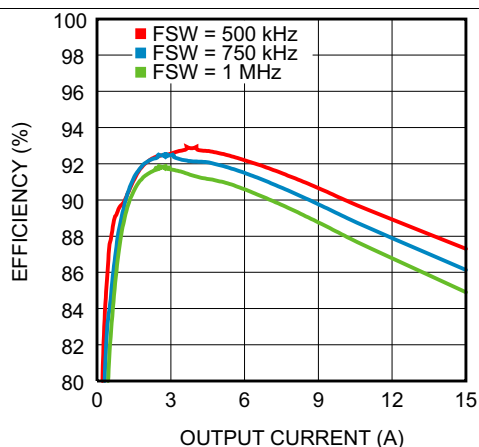


Figure 1. Efficiency

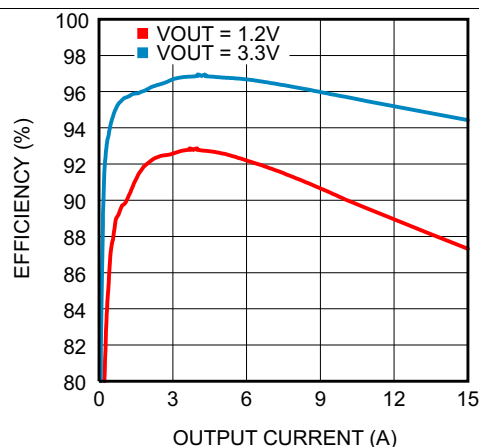


Figure 2. Efficiency

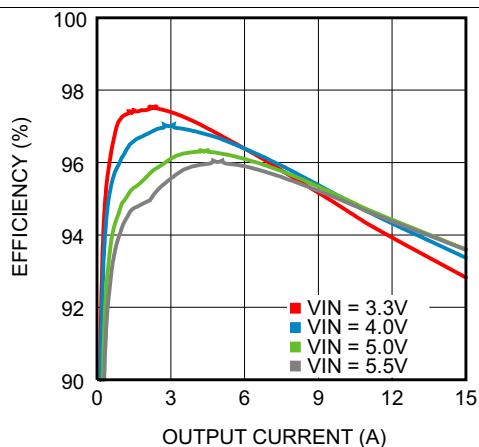


Figure 3. Efficiency ($V_{OUT} = 2.5\text{ V}$, $f_{SW} = 500\text{ kHz}$, Inductor P/N SER2010-601MLD)

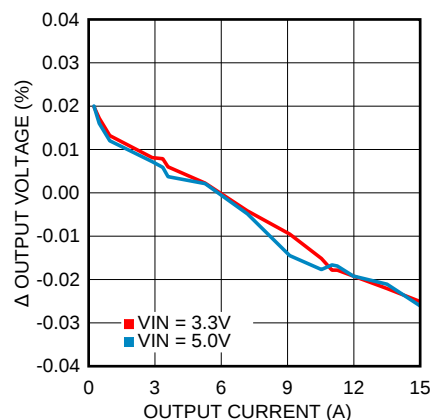


Figure 4. Load Regulation

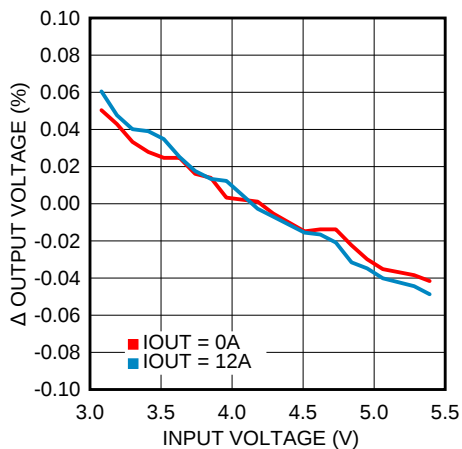


Figure 5. Line Regulation

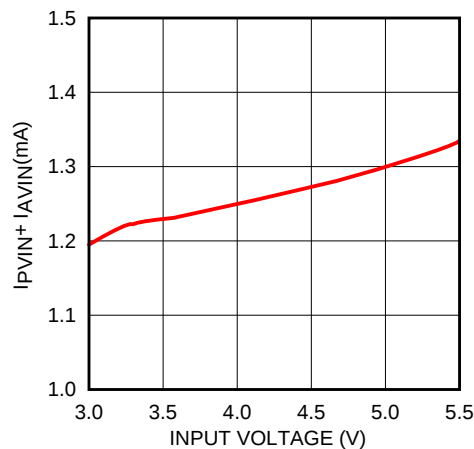


Figure 6. Non-Switching $I_{Q(TOTAL)}$ vs V_{IN}

Typical Characteristics (continued)

Unless otherwise specified: $V_{IN} = 5\text{ V}$, $V_{OUT} = 1.2\text{ V}$, $L_F = 0.56\text{ }\mu\text{H}$ ($1.8\text{ m}\Omega\text{ }R_{DCR}$), $C_{SS} = 33\text{ nF}$, $f_{SW} = 500\text{ kHz}$, $T_A = 25^\circ\text{C}$ for efficiency curves, loop gain plots and waveforms, and $T_J = 25^\circ\text{C}$ for all others.

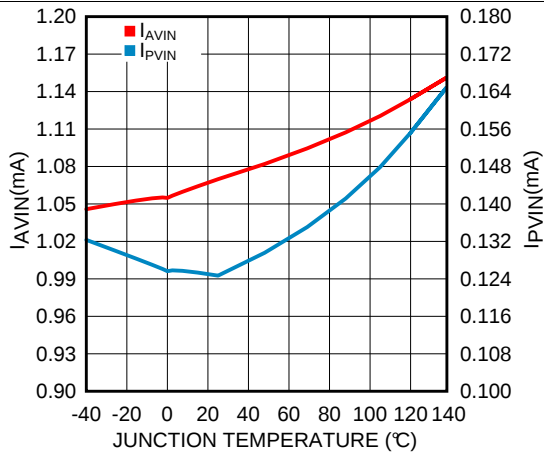


Figure 7. Non-Switching I_{AVIN} and I_{PVIN} vs Temperature

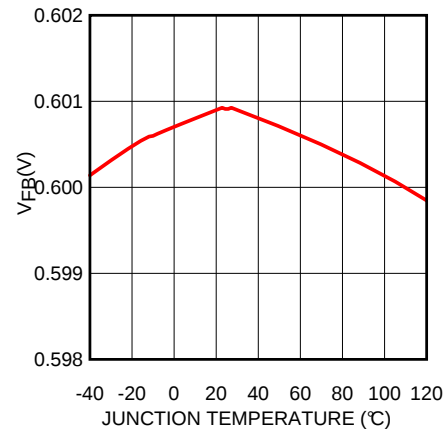


Figure 8. Feedback (FB) Voltage vs Temperature

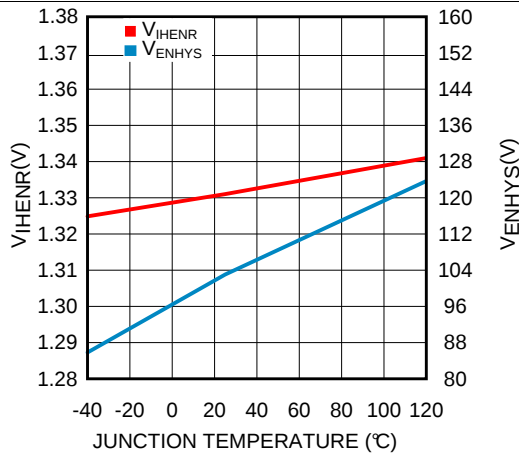


Figure 9. Enable Threshold and Hysteresis vs Temperature

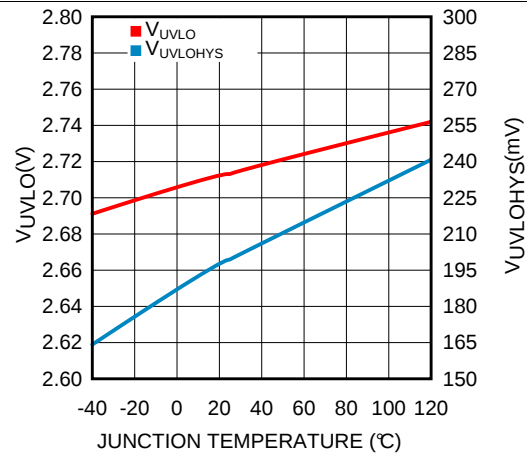


Figure 10. UVLO Threshold and Hysteresis vs Temperature

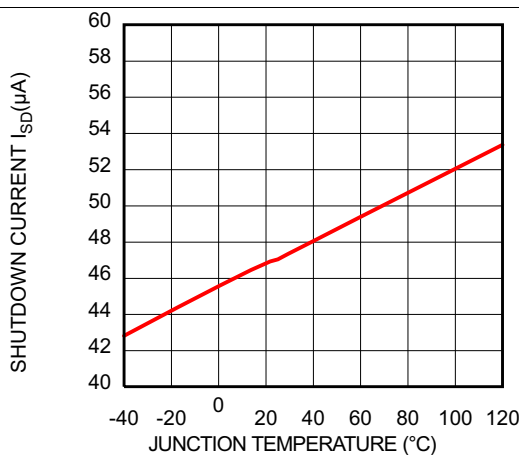


Figure 11. Enable Low Current vs Temperature

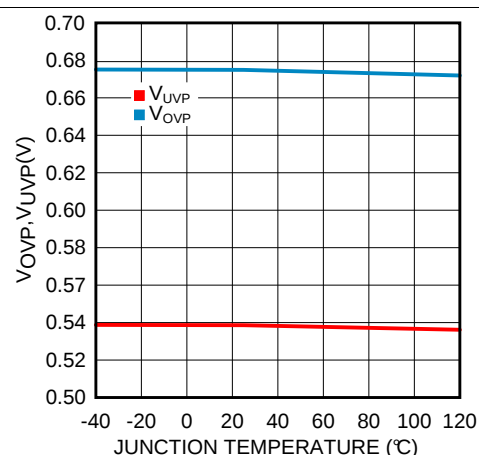


Figure 12. OVP/UVP Threshold vs Temperature

Typical Characteristics (continued)

Unless otherwise specified: $V_{IN} = 5\text{ V}$, $V_{OUT} = 1.2\text{ V}$, $L_F = 0.56\text{ }\mu\text{H}$ ($1.8\text{ m}\Omega\text{ }R_{DCR}$), $C_{SS} = 33\text{ nF}$, $f_{SW} = 500\text{ kHz}$, $T_A = 25^\circ\text{C}$ for efficiency curves, loop gain plots and waveforms, and $T_J = 25^\circ\text{C}$ for all others.

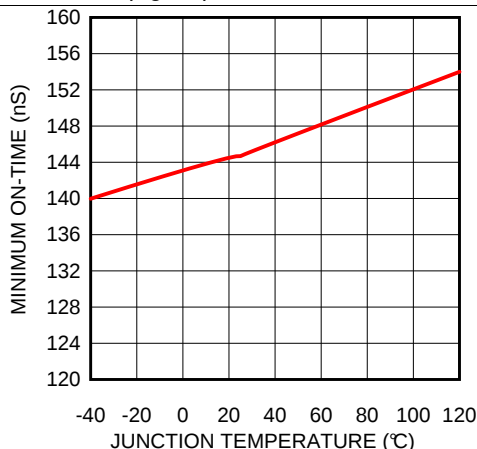


Figure 13. Minimum On-Time vs Temperature

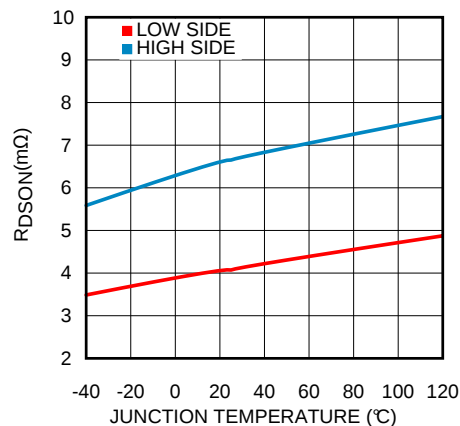


Figure 14. MOSFET On-State Resistance vs Temperature

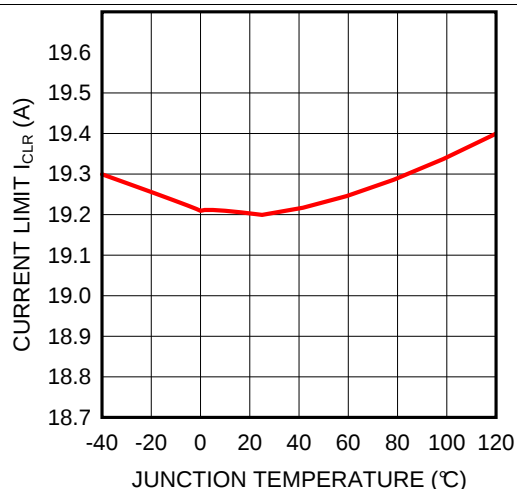


Figure 15. Peak Current Limit vs Temperature

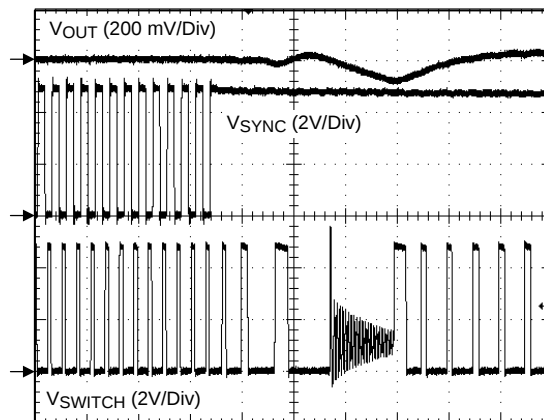


Figure 16. SYNC Signal Removed, 4 $\mu\text{s/Div}$

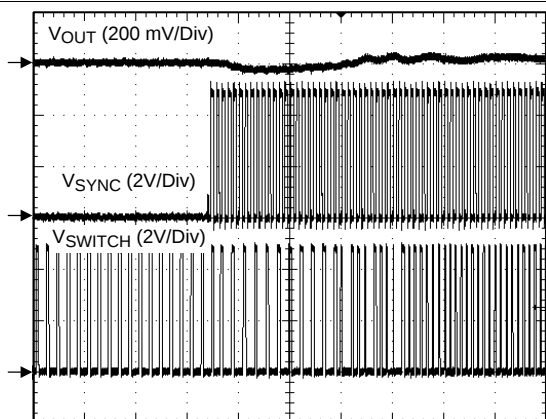


Figure 17. SYNC Signal Acquired, 10 $\mu\text{s/div}$

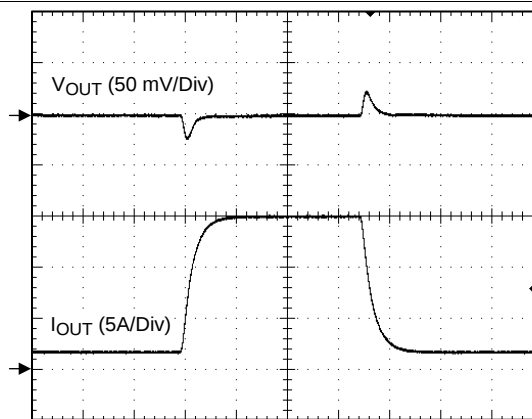


Figure 18. Load Transient Response, 100 $\mu\text{s/Div}$

Typical Characteristics (continued)

Unless otherwise specified: $V_{IN} = 5\text{ V}$, $V_{OUT} = 1.2\text{ V}$, $L_F = 0.56\text{ }\mu\text{H}$ ($1.8\text{ m}\Omega\text{ }R_{DCR}$), $C_{SS} = 33\text{ nF}$, $f_{SW} = 500\text{ kHz}$, $T_A = 25^\circ\text{C}$ for efficiency curves, loop gain plots and waveforms, and $T_J = 25^\circ\text{C}$ for all others.

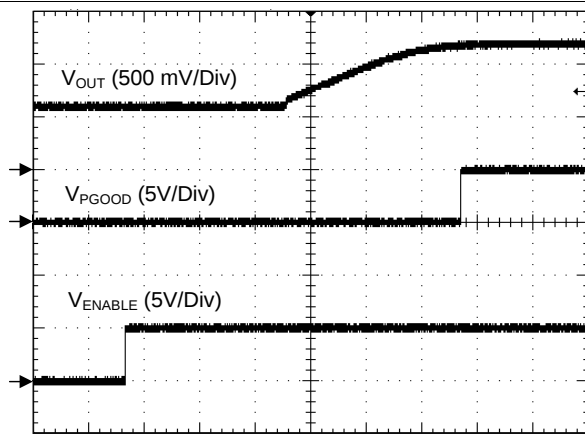


Figure 19. Startup with Prebiased Output, 2 ms/Div

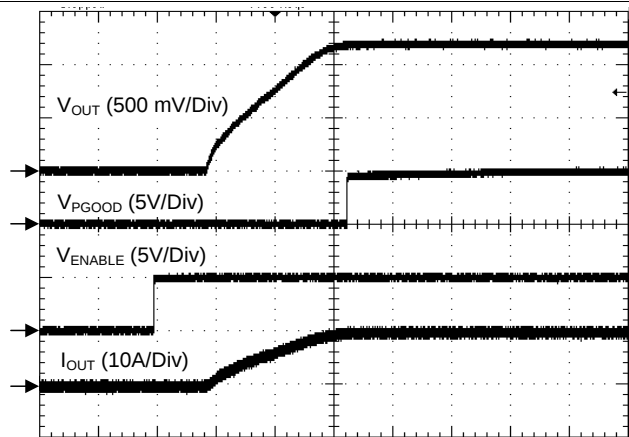


Figure 20. Startup with SS/TRK Open Circuit, 200 $\mu\text{s/Div}$

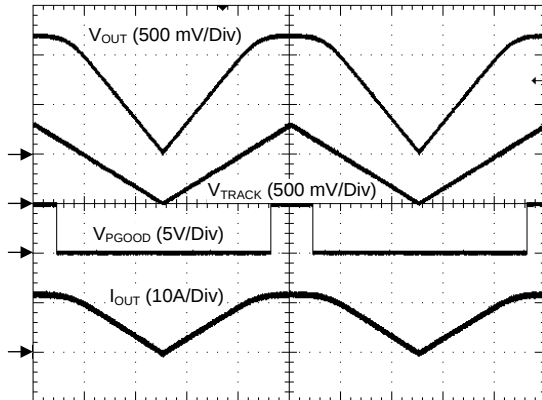


Figure 21. Startup with Tracking Signal Applied, 200 ms/Div

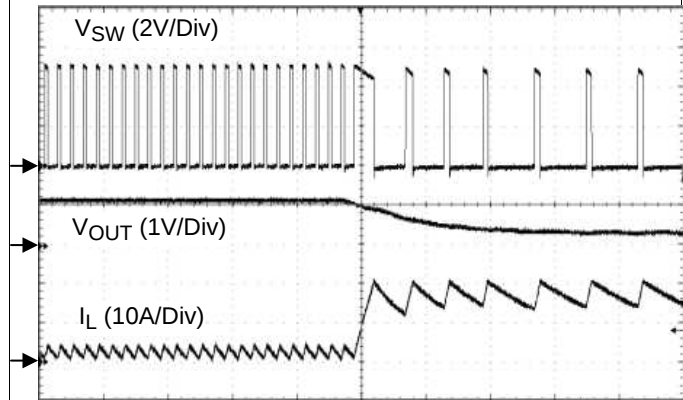


Figure 22. Output Overcurrent Condition, 10 $\mu\text{s/Div}$

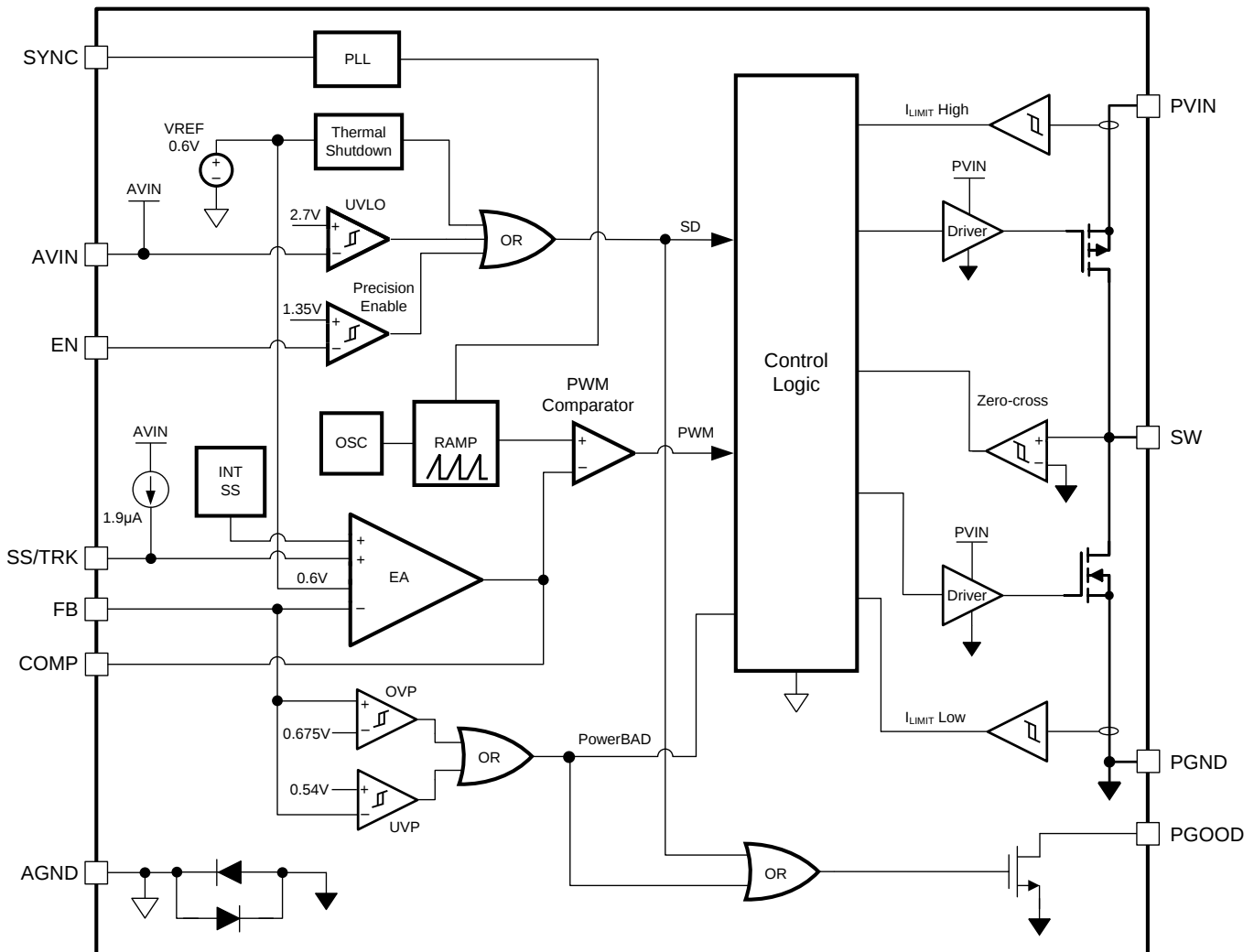
7 Detailed Description

7.1 Overview

The LM21215A synchronous buck regulator features all of the functions necessary to implement an efficient low-voltage converter using a minimum number of external components. This easy-to-use regulator features two integrated power MOSFET switches and is capable of supplying up to 15 A of continuous output current. Synchronous rectification yields high efficiency for low output voltage and high load current applications, whereas discontinuous conduction mode (DCM) with diode emulation mode (DEM) enables high-efficiency conversion with light load current conditions.

The regulator utilizes voltage-mode control with trailing-edge PWM modulation to optimize stability and transient response over the entire input voltage range. The device operates at high switching frequency, allowing the use of a small inductor yet still achieving high efficiency. The precision internal voltage reference allows output voltages as low as 0.6 V. Fault protection features include peak and valley current limiting, thermal shutdown, overvoltage protection, and undervoltage lockout. The device is available in the HTSSOP-20 package featuring an exposed pad to aid thermal dissipation. The LM21215A is ideal for numerous applications to efficiently step-down from a 5-V or 3.3-V bus.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Precision Enable

The EN pin allows the output of the device to be enabled or disabled with an external control signal. This pin is a precision analog input that enables the device when the voltage exceeds 1.35 V (typical). The EN pin has 110 mV of hysteresis and disables the output when the Enable voltage falls below 1.24 V (typical). If the EN pin is not used, it can be left open as it is pulled high by an internal 2-μA current source. Since the EN pin has a precise turn-on threshold, it can be used along with an external resistor divider network from VIN to configure the device to turn on at a precise input voltage.

7.3.2 Input Voltage UVLO

The LM21215A has a built-in undervoltage lockout protection circuit that prevents the device from switching until the input voltage reaches 2.7 V (typical). The UVLO threshold has 200 mV of hysteresis that prevents the device from responding to power-on glitches during startup. As mentioned above, adjust the turn-on threshold of the supply by using the precision enable pin and a resistor divider network connected to VIN. Please refer to [Figure 30](#) of the *Detailed Design Procedure* section for more detail.

7.3.3 Soft-Start Capability

When EN exceeds 1.35 V and AVIN is above its UVLO threshold of 2.7 V, the LM21215A begins charging the output linearly to the voltage setpoint dictated by the feedback resistor network. The LM21215A employs a user-adjustable soft-start circuit to set the output voltage ramp time during startup. A capacitor from SS/TRK to GND sets the required soft-start time. Once the enable voltage exceeds 1.35 V, an internal 1.9-μA current source begins to charge the soft-start capacitor. This allows the user to limit inrush currents due to a high output capacitance and avoid an overcurrent condition. Adding a soft-start capacitor also reduces the stress on the input rail. Use [Equation 1](#) to calculate the soft-start capacitance.

$$C_{SS} = \frac{t_{SS} \cdot I_{SS}}{0.6V}$$

where

- I_{SS} is nominally 1.9 μA
- t_{SS} is the desired startup time

(1)

If V_{IN} is higher than the UVLO level and Enable is toggled high, the soft-start sequence begins. There is a small delay between enable transitioning high and the beginning of the soft-start sequence. This delay allows the LM21215A to initialize its internal circuitry. Once the output has charged to 90% of the nominal output voltage, the PGOOD flag transitions high. This behavior is illustrated in [Figure 23](#).

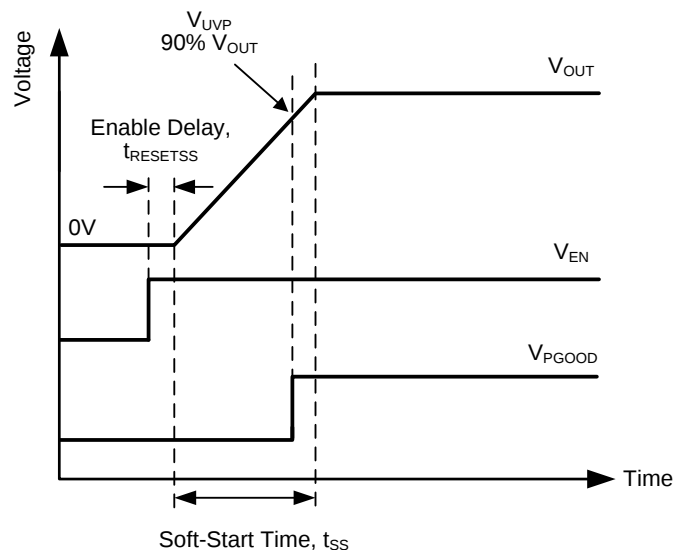


Figure 23. Soft-Start Timing

Feature Description (continued)

As shown above, the soft-start capacitance is set by the nominal feedback voltage level 0.6 V, the soft-start charging current I_{SS} , and the desired soft-start time. If a soft-start capacitor is not installed, the LM21215A defaults to a soft-start time of 500 μ s. The LM21215A cannot startup faster than 500 μ s. When Enable is cycled or the device enters UVLO, the soft-start capacitor is discharged to reset the startup process. This also occurs when the device enters short circuit mode following an overcurrent event.

7.3.4 PGOOD Indicator

The PGOOD flag provides the user with a way to monitor the status of the LM21215A. In order to use the PGOOD function, the application must provide a pullup resistor to a desired DC voltage, for example V_{IN} . PGOOD responds to a fault condition by pulling PGOOD low with the open-drain output. PGOOD pulls low on the following conditions: 1) V_{FB} moves above or below the V_{OVP} or V_{UVP} , respectively; 2) The EN voltage is brought below the Enable turn-off threshold; 3) A pre-biased output condition exists ($V_{FB} > V_{SS/TRK}$). PGOOD has 12 μ s and 15 μ s of built-in deglitch time for rising and falling edges, respectively.

Figure 24 shows the conditions that cause PGOOD to respond.

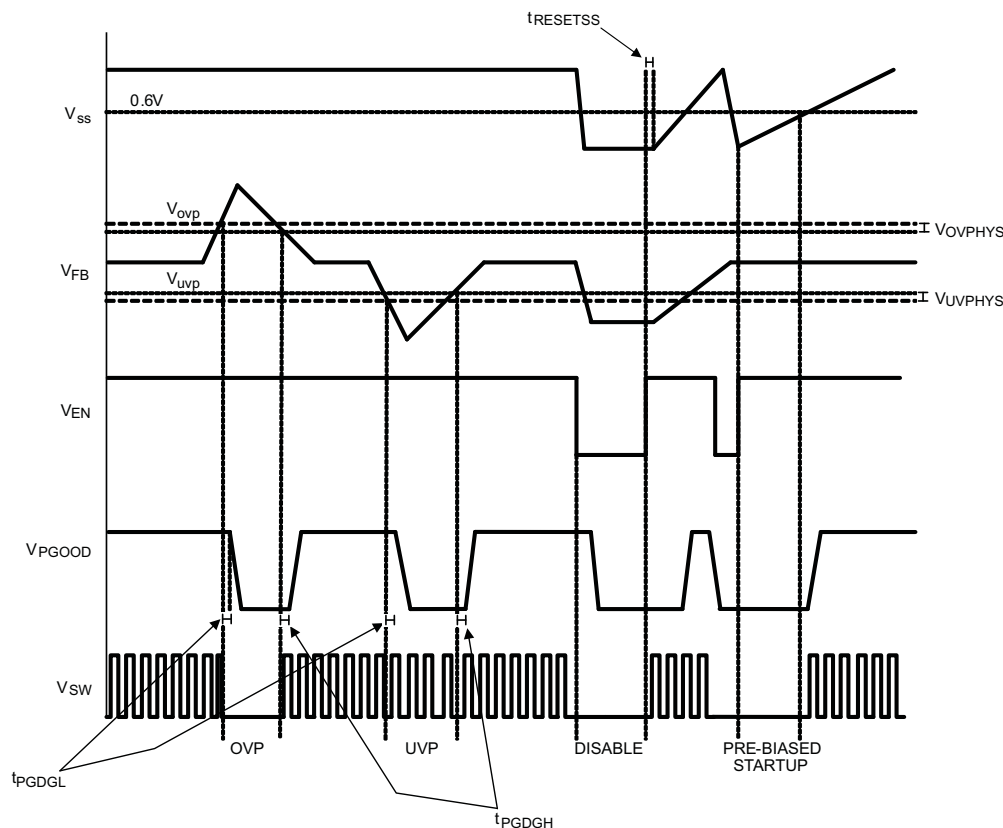


Figure 24. PGOOD Indicator Operation

7.3.5 Frequency Synchronization

The SYNC pin allows the LM21215A to be synchronized to an external clock frequency. When a clock signal within the allowable frequency range of 300 kHz to 1.5 MHz is present on SYNC, an internal PLL synchronizes the turn-on of the high-side MOSFET (SW voltage rising) to the negative edge of the clock signal, as seen in Figure 25.

The clock signal can be present on the SYNC pin before the device is powered on without loading of the clock signal. Alternatively, if a clock signal is not present while the device is powered up, the default switching frequency is 500 kHz. Once the clock signal is available, the device synchronizes to the clock frequency. The time required to achieve synchronization depends on the clock frequency.

Feature Description (continued)

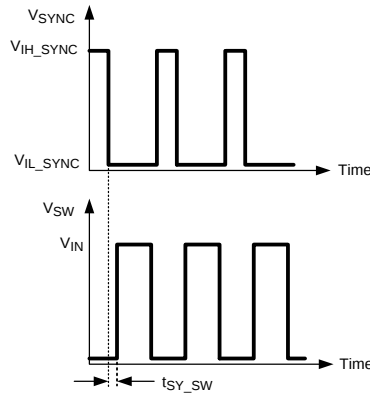


Figure 25. Frequency Synchronization

7.3.6 Current Limit

The LM21215A has overcurrent protection to avoid excessive current levels through the power MOSFETs and inductor. A current limit condition exists when the high-side MOSFET's current exceeds the rising current limit level, I_{CLR} . The control circuitry responds to this event by turning off the high-side MOSFET and turning on the low-side MOSFET. This forces a negative voltage on the inductor, thereby causing the inductor current to decrease. The high-side MOSFET does not conduct again until the lower current limit level, I_{CLF} , is sensed on the low-side MOSFET. At this point, the LM21215A resumes normal switching.

A current limit condition causes the internal soft-start voltage to ramp downward. After the internal soft-start ramps below the feedback (FB) voltage, nominally 0.6 V, FB begins to ramp downward, as well. This voltage foldback limits the power consumption in the device during a sustained overload. After the current limit condition is cleared, the internal soft-start voltage ramps up again. [Figure 26](#) describes current limit behavior including V_{SS} , V_{FB} , V_{OUT} and V_{SW} waveforms.

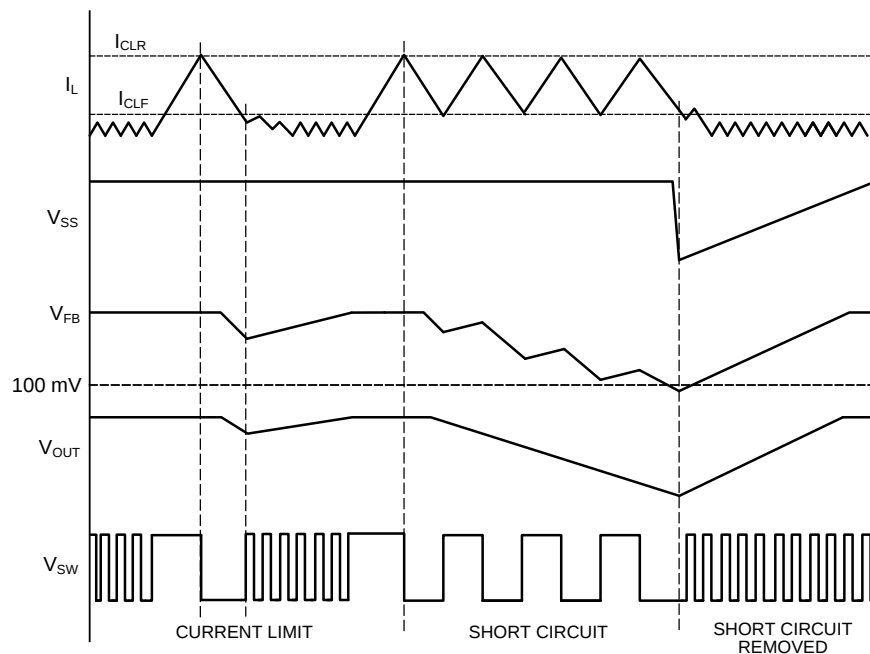


Figure 26. Current Limit Conditions

Feature Description (continued)

7.3.7 Short Circuit Protection

In an event that the output is shorted with a low impedance to ground, the LM21215A limits the current into the short by resetting the device. A short circuit condition is sensed as a current limit condition coinciding with a voltage on the FB pin that is lower than 100 mV. When this condition occurs, the device begins its reset sequence, turning off both power MOSFETs and discharging the soft-start capacitor after t_{RESETSS} (nominally 110 μs). The device then attempts to restart. If the short circuit condition still exists, it resets again, repeating until the short circuit condition is cleared. The reset prevents excessive power MOSFET dissipation and limits thermal stress during a short circuit fault condition.

7.4 Device Functional Modes

7.4.1 Light-Load Operation

The LM21215A maintains high efficiency when operating at light loads. Whenever the load current is reduced to a level less than half the peak-to-peak inductor ripple current, the device enters discontinuous conduction mode (DCM) and prevents negative inductor current. The low-side MOSFET then operates in diode emulation mode (DEM), conducting only positive inductor current. Calculate the critical conduction boundary using [Equation 2](#).

$$I_{\text{BOUNDARY}} = \frac{\Delta I_L}{2} = \frac{V_{\text{OUT}} \cdot (1-D)}{2 \cdot L_F \cdot F_{\text{SW}}} \quad (2)$$

Several diagrams are shown in [Figure 27](#) illustrating continuous conduction mode (CCM), discontinuous conduction mode (DCM), and the boundary condition.

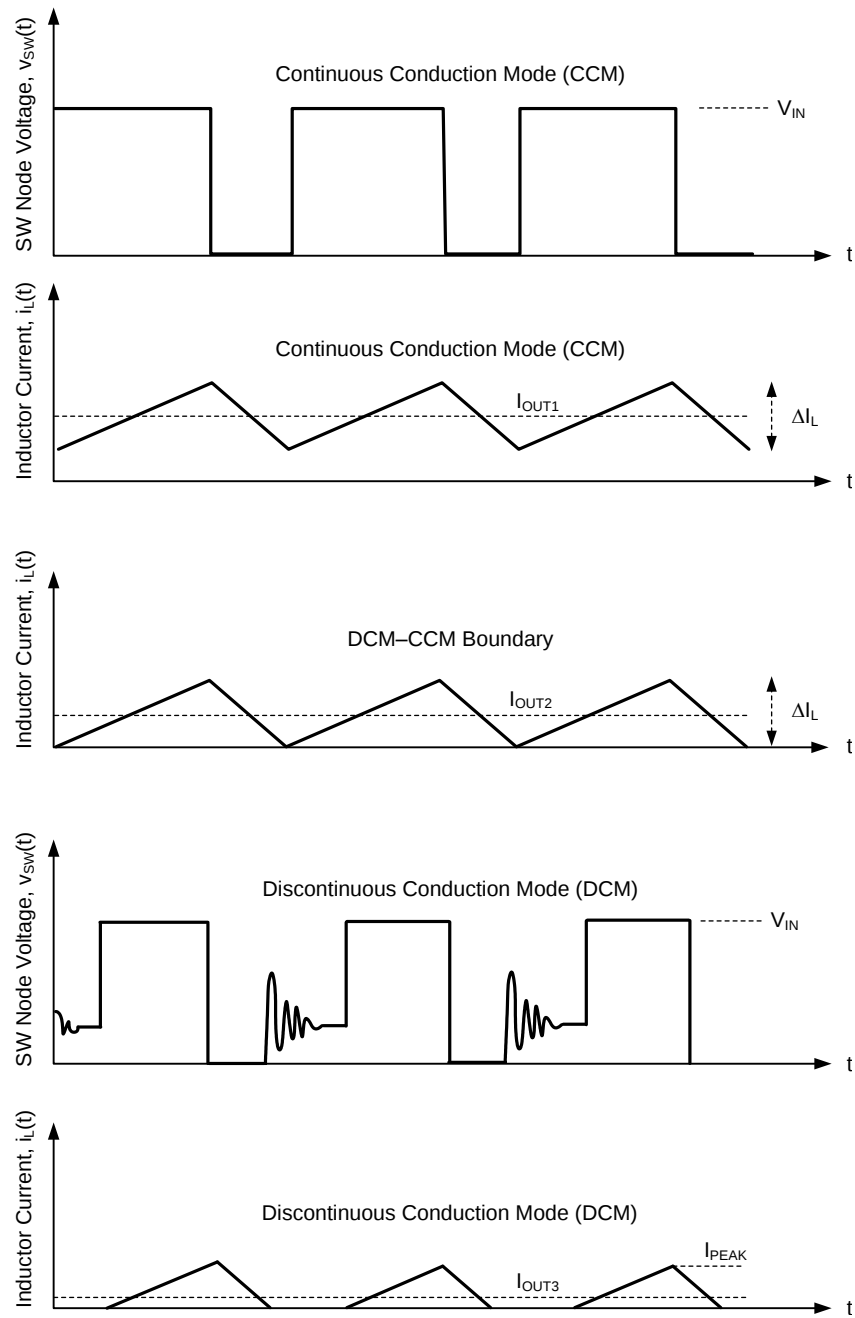
When the inductor current reaches zero, the SW node becomes high impedance. Resonant ringing occurs at SW as a result of the LC tank circuit formed by the filter inductor and the parasitic capacitance at the SW node. At very light loads, usually below 500 mA, several pulses may be skipped in between switching cycles, effectively reducing the switching frequency and further improving light-load efficiency.

7.4.2 Overvoltage and Undervoltage Handling

The LM21215A has built-in undervoltage protection (UVP) and overvoltage protection (OVP) using FB voltage comparators to control the power MOSFETs. The rising OVP threshold is typically set at 112.5% of the nominal voltage setpoint. Whenever excursions occur in the output voltage above the OVP threshold, the device terminates the present on-pulse, turns on the low-side MOSFET, and pulls PGOOD low. The low-side MOSFET remains on until either the FB voltage falls back into regulation or the inductor current zero-cross is detected. If the output reaches the falling UVP threshold, typically 90% of the nominal setpoint, the device continues switching and PGOOD is asserted and pulls low. As detailed in the [PGOOD Indicator](#) section, PGOOD has 15 μs of built-in deglitch time in response to a UVP or OVP condition to avoid false tripping during transient glitches.

7.4.3 Thermal Shutdown

Internal thermal shutdown circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. When activated, typically at 165°C, the LM21215A tri-states the power MOSFETs and resets soft start. After the junction temperature cools to approximately 155°C, the device starts up using the normal startup routine.

Device Functional Modes (continued)

Figure 27. LM21215A Modes of Operation

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The LM21215A is a synchronous buck DC/DC converter with a maximum output current of 15 A. The following design procedure assists with component selection for the LM21215A. Alternately, the [WEBENCH® Design Tool](#) is available to generate a complete design. With access to a comprehensive component database, this tool uses an iterative design procedure to create an optimized design, allowing the user to experiment with various design options. As well as numerous LM21215 reference designs populated in the TI Designs reference design library, the [LM21215A Quickstart Design Calculator](#) is also available as a free download.

8.2 Typical Applications

8.2.1 Typical Application 1

The schematic diagram of a 15-A regulator is given in [Figure 28](#). The target full-load efficiency in this example is 89% at an output voltage of 1.2 V and nominal input voltage of 5 V. The free-running switching frequency (with the SYNC pin open circuit) is 500 kHz. In terms of control loop performance, the target loop crossover frequency is 100 kHz with a phase margin in excess of 50°.

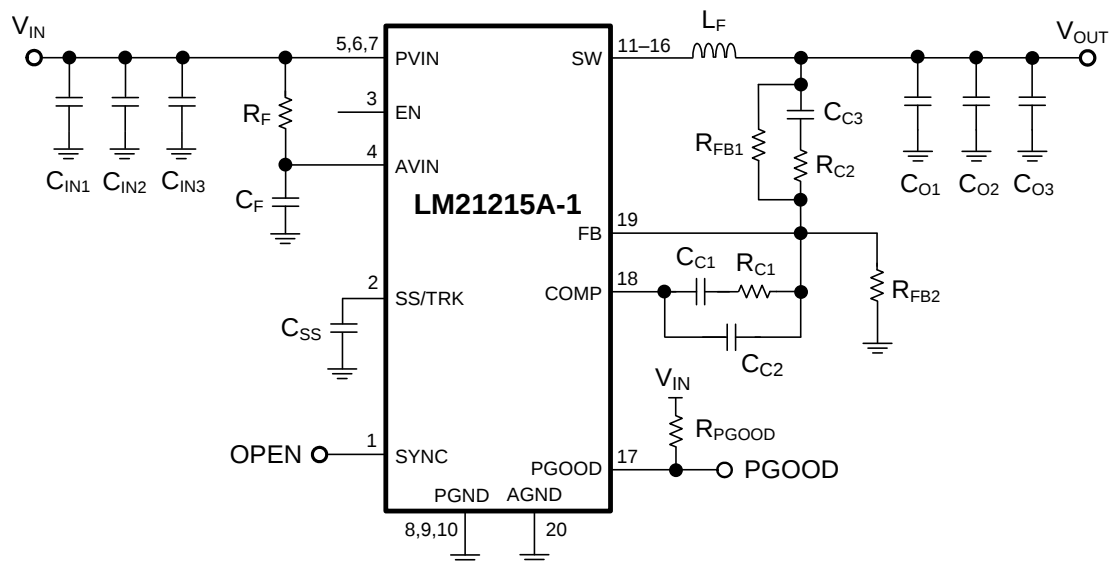


Figure 28. Typical Application Schematic 1

8.2.1.1 Design Requirements

An example of the step-by-step procedure to generate power stage and compensation component values using the typical application setup of [Figure 28](#) is given in [Table 1](#). The relevant design specifications are given in [Table 1](#). Here, $f_{\text{crossover}}$ is the desired loop crossover frequency, which generally is less than one-fifth of the switching frequency, and $\Delta V_{\text{OUT(pk-pk)}}$ is the peak-to-peak output voltage ripple.

Table 1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
V_{IN}	5 V
V_{OUT}	1.2 V
I_{OUT}	15 A
F_{SW}	500 kHz
$f_{crossover}$	100 kHz
$\Delta V_{OUT(pk-pk)}$	10 mV

8.2.1.2 Detailed Design Procedure

8.2.1.2.1 Custom Design With WEBENCH® Tools

[Click here](#) to create a custom design using the LM21215A device with the WEBENCH® Power Designer.

1. Start by entering the input voltage (V_{IN}), output voltage (V_{OUT}), and output current (I_{OUT}) requirements.
2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

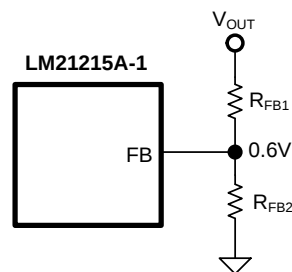
In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

8.2.1.2.2 Output Voltage Setpoint

The first step in designing an LM21215A application is to configure the output voltage setpoint by using a voltage divider between V_{OUT} and AGND, with the middle node connected to FB. When operating under steady state conditions, the LM21215A regulates V_{OUT} such that the FB voltage is driven to 0.6 V.


Figure 29. Setting the Output Voltage by Feedback Resistor Divider

A good starting point for the lower feedback resistor, R_{FB2} , is 10 kΩ. Calculate R_{FB1} using [Equation 3](#).

$$V_{OUT} = 0.6V \cdot \left(1 + \frac{R_{FB1}}{R_{FB2}} \right) \quad (3)$$

8.2.1.2.3 Precision Enable

The Enable (EN) pin of the LM21215A allows the output to be toggled on and off. This pin is a precision analog input. When the voltage exceeds 1.35 V, the converter begins to regulate the output voltage as long as AVIN has exceeded the UVLO threshold voltage of 2.7 V. There is an internal pullup current source of 2 μ A connected to EN. If enable is not used, the device turns on automatically. Also, if EN is not toggled directly, the device can be set to turn on at a certain input voltage higher than the internal UVLO rising threshold. This is achieved with an external resistor divider from AVIN to EN and EN to AGND as shown in Figure 30.

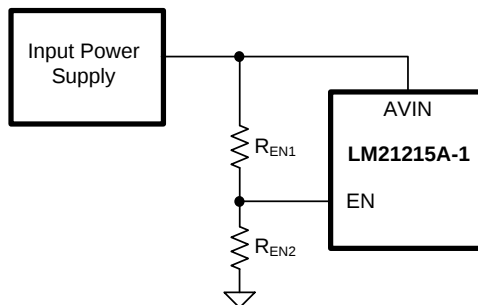


Figure 30. Input Voltage Turn-on Setpoint Configured by Enable Resistor Divider

The resistances of R_{EN1} and R_{EN2} are chosen to allow EN to reach its rising threshold voltage at the desired the input supply voltage. With the enable current source included, use Equation 4 to solve for R_{EN1} .

$$R_{EN1} = R_{EN2} \cdot \frac{V_{IN} - 1.35V}{1.35V - I_{EN} \cdot R_{EN2}}$$

where

- R_{EN1} is the resistor from V_{IN} to EN
- R_{EN2} is the resistor from EN to AGND
- I_{EN} is the internal enable pullup current (2 μ A)
- 1.35 V is the precision enable rising threshold voltage

(4)

Typical values for R_{EN2} range from 10 k Ω to 100 k Ω .

8.2.1.2.4 Filter Inductor Selection

The filter inductor, designated L_F , chosen for the application influences the ripple current and the efficiency of the converter. The first selection criteria is to define the buck converter inductor ripple current ΔI_L , typically selected between 20% to 40% of the maximum output current. Figure 31 shows the ripple current in a conventional buck converter operating in continuous conduction mode. Larger ripple current results in a lower inductance, which leads to lower inductor DC resistance (DCR) and improved efficiency. However, larger ripple current causes the LM21215A to operate in DCM at a higher average output current.

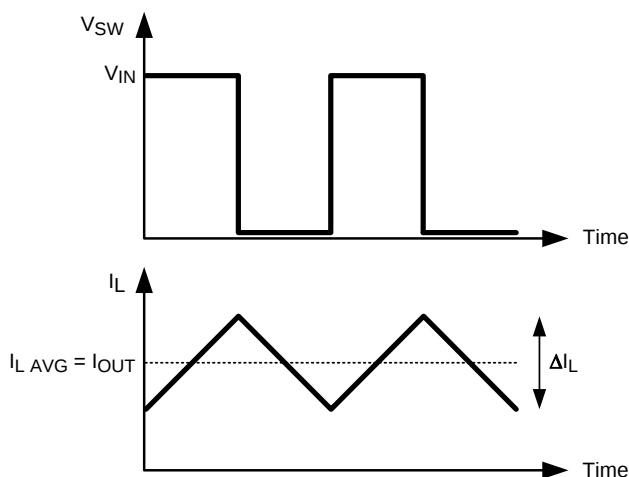


Figure 31. Switch (SW) Voltage and Inductor Current Waveforms

Once the ripple current has been determined, calculate the appropriate inductance using [Equation 5](#).

$$L_F = \frac{V_{OUT} \cdot (1-D)}{\Delta I_L \cdot F_{SW}} \quad (5)$$

A 0.56-μH inductor with 1.8-mΩ DCR meets the application requirements here. The peak inductor current at full load corresponds to the maximum output current plus the ripple current, as shown by [Equation 6](#).

$$I_{L(max)} = I_{OUT(max)} + \frac{\Delta I_{L(max)}}{2} \quad (6)$$

Choose an inductor with a saturation current rating at maximum operating temperature that is higher than the overcurrent protection limit. In general, lower inductance is desirable in switching converters because it equates to faster transient response, lower inductor DCR, and reduced size for more compact designs. However, too low of an inductance implies large inductor ripple current such that the overcurrent protection circuit is falsely triggered at the full load. Larger inductor ripple current also implies higher output voltage ripple.

8.2.1.2.5 Output Capacitor Selection

The output capacitor, designated C_{OUT} , filters the inductor ripple current and provides a source of charge for transient load conditions. A wide range of output capacitors may be used with the LM21215A that provide various advantages. The best performance is typically obtained using ceramic, SP or OSCON type chemistries. Typical trade-offs are that the ceramic capacitor provides extremely low ESR to reduce the output ripple voltage and noise spikes, while the SP and OSCON capacitors provide a large bulk capacitance in a small volume for transient loading conditions.

When selecting an output capacitor, the two performance characteristics to consider are the output voltage ripple and load transient response. Approximate the output voltage ripple by using [Equation 7](#).

$$\Delta V_{OUT} = \Delta I_L \sqrt{R_{ESR}^2 + \left(\frac{1}{8 \cdot F_{SW} \cdot C_{OUT}} \right)^2}$$

where

- ΔV_{OUT} is the peak-to-peak output voltage ripple
- R_{ESR} is the effective series resistance (ESR) of the output capacitor
- F_{SW} is the switching frequency
- C_{OUT} is the *effective* output capacitance

(7)

The amount of output voltage ripple is application specific. A general recommendation is to keep the output ripple less than 1% of the rated output voltage. Keep in mind that ceramic capacitors are sometimes preferred because they have very low ESR. However, depending on package and voltage rating of the capacitor, the effective in-circuit capacitance can drop significantly with applied voltage. The output capacitor selection also affects the output voltage droop during a load transient. The peak deviation of the output voltage during a load transient is dependent on many factors. An approximation of the transient dip ignoring loop bandwidth is obtained using [Equation 8](#):

$$V_{\text{DROOP}} = \Delta I_{\text{OUT-STEP}} \cdot R_{\text{ESR}} + \frac{L_F \cdot \Delta I_{\text{OUT-STEP}}^2}{C_{\text{OUT}} \cdot (V_{\text{IN}} - V_{\text{OUT}})}$$

where

- C_{OUT} is the minimum required output capacitance
- L_F is the filter inductance
- V_{DROOP} is the output voltage deviation ignoring loop bandwidth considerations
- $\Delta I_{\text{OUT-STEP}}$ is the load step change
- R_{ESR} is the output capacitor ESR
- V_{IN} is the input voltage
- V_{OUT} is the output voltage setpoint

(8)

Three 100- μF , 6.3-V ceramic capacitors with X5R dielectric and 1210 footprint are selected here based on a review of the capacitor's tolerance and voltage coefficient to meet output ripple specification.

8.2.1.2.6 Input Capacitor Selection

High quality input capacitors are necessary to limit the input voltage ripple while supplying switching-frequency AC current to the buck power stage. It is generally recommended to use X5R or X7R dielectric ceramic capacitors, thus providing low impedance and high RMS current rating over a wide temperature range. To minimize the parasitic inductance in the switching loop, position the input capacitors as close as possible to the PVIN and PGND pins. A good approximation for the required ripple current rating is given by [Equation 9](#).

$$I_{\text{RMS-CIN}} = I_{\text{OUT}} \cdot \frac{\sqrt{V_{\text{OUT}} \cdot (V_{\text{IN}} - V_{\text{OUT}})}}{V_{\text{IN}}} \quad (9)$$

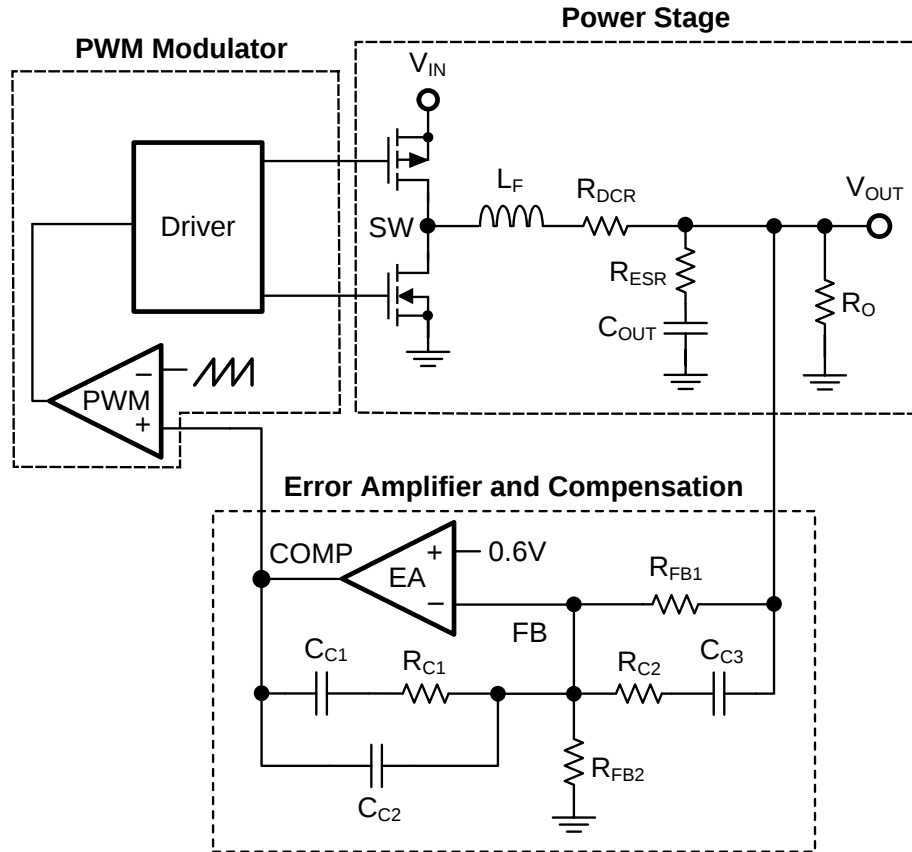
The highest input capacitor RMS current occurs at 50% duty cycle, at which point the RMS ripple current rating should be greater than half the output current. Place low ESR ceramic capacitors in parallel with higher value bulk capacitance to provide optimized input filtering for the regulator and damping to mitigate the effects of input parasitic inductance resonating with high-Q ceramics. One bulk capacitor of sufficiently high current rating and one or two 22- μF 10-V X7R ceramic decoupling capacitors are usually sufficient. Select the input bulk capacitor based on its ripple current rating and operating temperature.

When operating at low input voltages (3.3 V or lower), additional capacitance may be necessary to avoid triggering an undervoltage condition during an output current transient. This depends on the impedance between the input voltage supply and the LM21215A, as well as the magnitude and slew rate of the load transient.

The AVIN pin requires a 1- μF ceramic capacitor to AGND and a 1- Ω resistor to PVIN. This RC network filters inherent noise on PVIN from the sensitive analog circuitry connected to AVIN.

8.2.1.2.7 Control Loop Compensation

This section walks through the various steps in obtaining the open-loop transfer function. There are three main blocks of a voltage-mode buck converter that the power supply designer must consider when designing the control system: the power stage, the PWM modulator, and the compensated error amplifier. The control loop architecture of a voltage-mode buck converter is provided in [Figure 32](#).


Figure 32. Voltage-mode Buck Converter Architecture

The power stage consists of the filter inductor (L_F) with DCR (DC resistance R_{DCR}), output capacitor (C_{OUT}) with ESR (effective series resistance R_{ESR}), and load resistance (R_O). The LM21215A incorporates a high-bandwidth error amplifier between the FB and COMP pins to achieve high loop bandwidth. The error amplifier (EA) constantly regulates FB to 0.6 V. The compensation component network around the error amplifier establish system stability. The modulator creates the duty cycle command by comparing the error amplifier output with an internally-generated PWM ramp set at the switching frequency.

There are three transfer functions that are taken into consideration when obtaining the total open-loop transfer function; COMP-to-duty cycle (modulator), duty cycle-to- V_{OUT} (power stage), and V_{OUT} -to-COMP (compensator). If ΔV_{RAMP} is the peak-to-peak ramp voltage (nominally 0.8 V), the COMP-to-duty cycle transfer function is simply the PWM modulator gain given by [Equation 10](#).

$$G_{PWM} = \frac{1}{\Delta V_{RAMP}} \quad (10)$$

The duty cycle-to-output transfer function includes the filter inductor, output capacitor, and output load resistance. The inductor and capacitor create a pair of complex poles at the LC tank frequency expressed by [Equation 11](#).

$$f_{LC} = \frac{1}{2 \cdot \pi} \cdot \sqrt{\frac{1}{L_F \cdot C_{OUT} \cdot \left(\frac{R_O + R_{ESR}}{R_O + R_{DCR}} \right)}} \quad (11)$$

In addition to two complex poles, a left half plane zero is created by the output capacitor ESR located at a frequency described by [Equation 12](#).

$$f_{ESR} = \frac{1}{2 \cdot \pi \cdot C_{OUT} \cdot R_{ESR}} \quad (12)$$

A Bode plot showing the –40dB/decade power stage response is shown in [Figure 33](#)

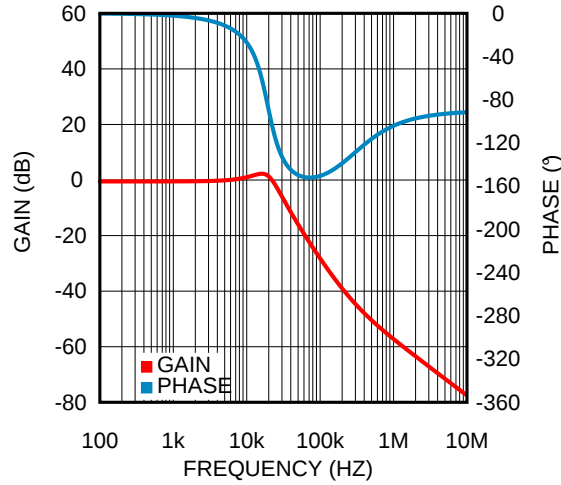


Figure 33. Power Stage Bode Plot

The complex poles created by the filter inductor and output capacitor cause a 180° phase lag. The phase is boosted back up to –90° by the output capacitor ESR zero. The compensator must provide sufficient phase boost to stabilize the loop response. The type-III compensation network shown around the error amplifier in [Figure 32](#) creates two poles, two zeros and a pole at the origin. Placing these poles and zeros at the correct frequencies stabilizes the closed loop response. The compensator transfer function is given by [Equation 13](#).

$$G_C(s) = K_{mid} \frac{\left(1 + \frac{2 \cdot \pi \cdot f_{z1}}{s}\right) \cdot \left(1 + \frac{s}{2 \cdot \pi \cdot f_{z2}}\right)}{\left(1 + \frac{s}{2 \cdot \pi \cdot f_{p1}}\right) \cdot \left(1 + \frac{s}{2 \cdot \pi \cdot f_{p2}}\right)}$$

where

- K_{mid} is the mid-band gain, R_{C1}/R_{FB1} (13)

The pole located at the origin gives high open-loop gain at DC, translating into improved load regulation accuracy. This pole occurs at a very low frequency due to the finite gain of the error amplifier; however, its location is approximated at DC for the purposes of compensation. The other two poles and two zeros are located accordingly to stabilize the voltage-mode loop depending on the power stage complex poles and their quality factor, Q. [Figure 34](#) illustrates a typical type-III compensator transfer function.

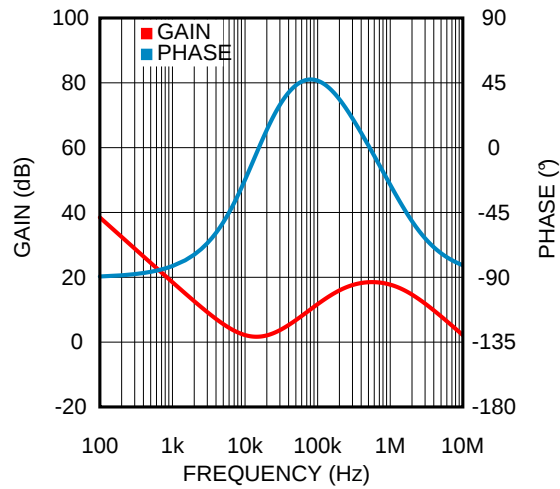


Figure 34. Type-III Compensation Network Bode Plot

As seen in Figure 34, the two compensator zeros located at ($f_{LC}/2$, f_{LC}) provide a phase boost. This mitigates the effect of the phase loss from the output filter. The compensation network also adds two poles to the system. One pole is located at the output capacitor ESR zero (f_{ESR}) and the other pole is at half the switching frequency ($F_{SW}/2$) to roll off the high frequency response.

The dependency of the pole and zero locations on the compensation components is described as follows:

$$f_{Z1} = \frac{f_{LC}}{2} = \frac{1}{2 \cdot \pi \cdot R_{C1} \cdot C_{C1}}$$

$$f_{Z2} = f_{LC} = \frac{1}{2 \cdot \pi \cdot (R_{C1} + R_{FB1}) \cdot C_{C3}}$$

$$f_{P1} = f_{ESR} = \frac{1}{2 \cdot \pi \cdot R_{C2} \cdot C_{C3}}$$

$$f_{P2} = \frac{F_{SW}}{2} = \frac{C_{C1} + C_{C2}}{2 \cdot \pi \cdot R_{C1} \cdot C_{C1} \cdot C_{C2}}$$

The output capacitance, C_{OUT} , depends on capacitor chemistry and bias voltage. For multi-layer ceramic capacitors (MLCC), the total capacitance degrades as the DC bias voltage is increased. To accurately calculate and optimize the compensation network, it is advisable to determine the effective capacitance of the output capacitors when biased at the output voltage.

The example given here is the total output capacitance using three MLCC output capacitors biased at 1.2 V, as seen in the typical application schematic of Figure 28. 50% capacitance derating is assumed.

NOTE

It is more conservative, from a stability standpoint, to err on the side of a lower output capacitance in the compensation calculations rather than a higher, as this will result in a lower bandwidth but increased phase margin.

First, choose a resistance for R_{FB1} , a typical value being 10 kΩ. From this, calculate the resistance of R_{C1} using Equation 14 to set the mid-band gain such that the desired crossover frequency is achieved.

$$R_{C1} = \frac{f_{crossover}}{f_{LC}} \cdot \frac{\Delta V_{RAMP}}{\Delta V_{IN}} \cdot R_{FB1} = \frac{100 \text{ kHz}}{17.4 \text{ kHz}} \cdot \frac{0.8 \text{ V}}{5 \text{ V}} \cdot 10 \text{ k}\Omega = 9.2 \text{ k}\Omega \quad (14)$$

Next, calculate the capacitance of C_{C1} by placing a zero at half of the LC double pole frequency (f_{LC}):

$$C_{C1} = \frac{1}{\pi \cdot f_{LC} \cdot R_{C1}} = 1.99 \text{ nF} \quad (15)$$

Now calculate C_{C2} to place a pole at half of the switching frequency and R_{C2} to place the second zero at the LC double pole frequency:

$$C_{C2} = \frac{C_{C1}}{\pi \cdot F_{SW} \cdot R_{C1} \cdot C_{C1} - 1} = 71 \text{ pF} \quad (16)$$

$$R_{C2} = \frac{R_{C2} \cdot f_{ESR}}{f_{ESR} - f_{LC}} = 166 \Omega \quad (17)$$

Last, derive capacitance of C_{C3} to place a pole at the same frequency as the output capacitor ESR zero:

$$C_{C3} = \frac{1}{2 \cdot \pi \cdot f_{ESR} \cdot R_{C2}} = 898 \text{ pF} \quad (18)$$

An illustration of the total loop response is seen in [Figure 35](#).

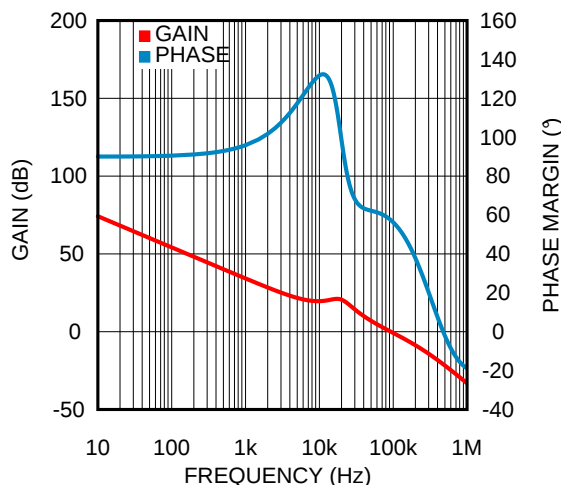


Figure 35. Loop Response

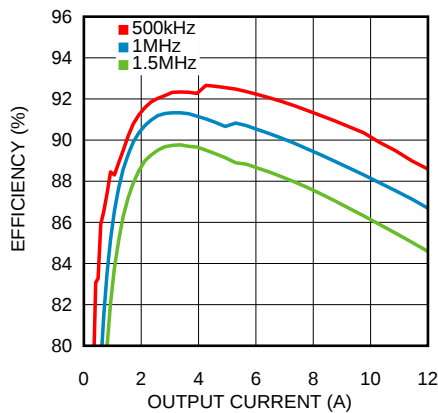
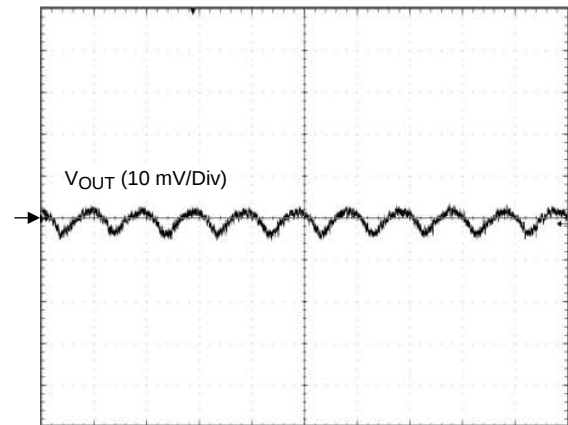
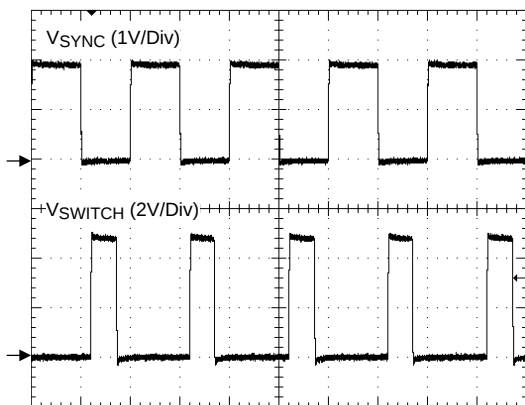
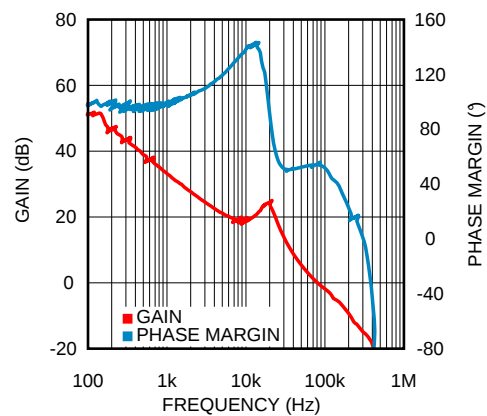
It is important to verify the stability either by observing the load transient response or by using a network analyzer. A phase margin between 45° and 70° is usually desired for voltage-mode converter circuits. Excessive phase margin causes slow system response to load transients whereas low phase margin leads to an oscillatory load transient response. If the peak deviation of the load transient response is larger than required, increasing $f_{crossover}$ and recalculating the compensation components may help but usually at the expense of phase margin.

Table 2. Bill of Materials ($V_{IN} = 3.3\text{ V to }5.5\text{ V}$, $V_{OUT} = 1.2\text{ V}$, $I_{OUT} = 15\text{ A}$, $f_{SW} = 500\text{ kHz}$)

REF DES	DESCRIPTION	VENDOR	PART NUMBER	QUANTITY
C_F	CAP, CERM, 1 μF , 10 V, $\pm 10\%$, X7R, 0603	MuRata	GRM188R71A105KA61D	1
C_{IN1} , C_{IN2} , C_{IN3} , C_{O1} , C_{O2} , C_{O3}	CAP, CERM, 100 μF , 6.3 V, $\pm 20\%$, X5R, 1206	MuRata	GRM31CR60J107ME39L	6
C_{C1}	CAP, CERM, 1800 pF, 50 V, $\pm 5\%$, C0G/NP0, 0603	TDK	C1608C0G1H182J	1
C_{C2}	CAP, CERM, 68 pF, 50 V, $\pm 5\%$, C0G/NP0, 0603	TDK	C1608C0G1H680J	1
C_{C3}	CAP, CERM, 820 pF, 50 V, $\pm 5\%$, C0G/NP0, 0603	TDK	C1608C0G1H821J	1
C_{SS}	CAP, CERM, 0.033 μF , 16 V, $\pm 10\%$, X7R, 0603	MuRata	GRM188R71C333KA01D	1
L_F	Inductor, Powdered Iron, 560 nH, 27.5A, 1.8 m Ω , SMD	Vishay Dale	IHLP4040DZERR56M01	1
R_F	RES, 1 Ω , 5%, 0.1 W, 0603	Vishay Dale	CRCW06031R00JNEA	1
R_{C1}	RES, 9.31 k Ω , 1%, 0.1 W, 0603	Vishay Dale	CRCW06039K31FKEA	1
R_{C2}	RES, 165 Ω , 1%, 0.1 W, 0603	Vishay Dale	CRCW0603165RFKEA	1
R_{FB1} , R_{FB2} , R_{PGOOD}	RES, 10 k Ω , 1%, 0.1 W, 0603	Vishay Dale	CRCW060310K0FKEA	3
U_1	LM21215A Synchronous Buck Regulator	TI	LM21215AMH-1/NOPB	1

8.2.1.3 Application Curves

For additional details on the waveforms shown in this section, please refer to application note [AN-2131 LM21215A Evaluation Board](#), [SNVA477](#).


Figure 36. Efficiency vs Load Current, $V_{OUT} = 1.2\text{ V}$

Figure 37. Output Ripple Voltage Waveform (1 $\mu\text{s/Div}$)

Figure 38. SW and SYNC Voltage Waveforms (1 $\mu\text{s/Div}$)

Figure 39. Bode Plot

8.2.2 Typical Application 2

The schematic diagram of a DC/DC regulator with 8-A output current is given by [Figure 40](#).

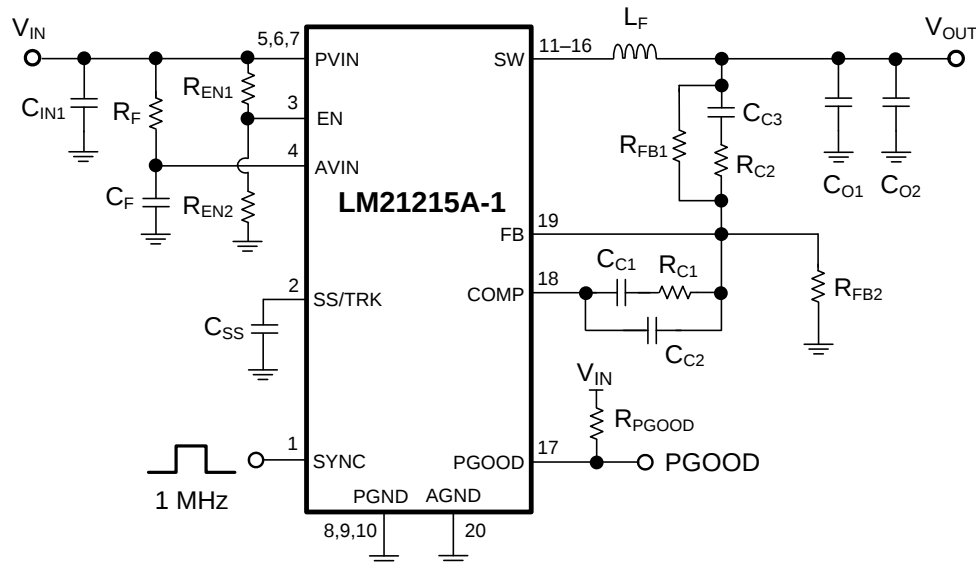


Figure 40. Typical Application Schematic 2

8.2.2.1 Design Requirements

Output voltage setpoint is 0.9 V and the input voltage ranges from 4 V to 5.5 V. The switching frequency is set by means of an external synchronization signal at 1 MHz. The output voltage soft-start time is 10 ms.

8.2.2.2 Detailed Design Procedure

Follow the detailed design procedure in [Typical Application 1](#). The relevant power stage and small-signal components are listed in [Table 3](#).

Table 3. Bill of Materials ($V_{IN} = 4\text{ V to }5.5\text{ V}$, $V_{OUT} = 0.9\text{ V}$, $I_{OUT} = 8\text{ A}$, $F_{SW} = 1\text{ MHz}$)

REF DES	DESCRIPTION	VENDOR	PART NUMBER	QUANTITY
C _F	CAP, CERM, 1 μF , 10 V, $\pm 10\%$, X7R, 0603	MuRata	GRM188R71A105KA61D	1
C _{IN1} , C _{O1} , C _{O2}	CAP, CERM, 100 μF , 6.3 V, $\pm 20\%$, X5R, 1206	MuRata	GRM31CR60J107ME39L	3
C _{C1}	CAP, CERM, 1800 pF, 50 V, $\pm 5\%$, C0G/NP0, 0603	MuRata	GRM1885C1H182JA01D	1
C _{C2}	CAP, CERM, 68 pF, 50 V, $\pm 5\%$, C0G/NP0, 0603	TDK	C1608C0G1H680J	1
C _{C3}	CAP, CERM, 470 pF, 50 V, $\pm 5\%$, C0G/NP0, 0603	TDK	C1608C0G1H471J	1
C _{SS}	CAP, CERM, 0.033 μF , 16 V, $\pm 10\%$, X7R, 0603	MuRata	GRM188R71C333KA01D	1
L _F	Inductor, Shielded Core, 240 nH, 20 A, 1 m Ω , SMD	Würth	744314024	1
R _F	RES, 1 Ω , 5%, 0.1 W, 0603	Vishay Dale	CRCW06031R00JNEA	1
R _{C1}	RES, 4.87 k Ω , 1%, 0.1 W, 0603	Vishay Dale	CRCW06034K87FKEA	1
R _{C2}	RES, 210 Ω , 1%, 0.1 W, 0603	Vishay Dale	CRCW0603210RFKEA	1
R _{EN1} , R _{FB1} , R _{PGOOD}	RES, 10 k Ω , 1%, 0.1 W, 0603	Vishay Dale	CRCW060310K0FKEA	3
R _{EN2}	RES, 19.6 k Ω , 1%, 0.1 W, 0603	Vishay Dale	CRCW060319K6FKEA	1
R _{FB2}	RES, 20 k Ω , 1%, 0.1 W, 0603	Vishay Dale	CRCW060320K0FKEA	1
U ₁	LM21215A Synchronous Buck Regulator	TI	LM21215AMH-1/NOPB	1

9 Power Supply Recommendations

The LM21215A converter is designed to operate from an input voltage supply range between 2.95 V and 5.5 V. The characteristics of the input supply must be compatible with the [Absolute Maximum Ratings](#) and [Recommended Operating Conditions](#) tables. In addition, the input supply must be capable of delivering the required input current to the fully-loaded regulator. Estimate the average input current with [Equation 19](#), where η is the efficiency:

$$I_{IN} = \frac{V_{OUT} \cdot I_{OUT}}{V_{IN} \cdot \eta} \quad (19)$$

If the converter is connected to an input supply through long wires or PCB traces with large impedance, special care is required to achieve stable performance. The parasitic inductance and resistance of the input cables may have an adverse affect on converter operation. The parasitic inductance in combination with the low ESR ceramic input capacitors form an under-damped resonant circuit. This circuit can cause overvoltage transients at PVIN each time the input supply is cycled on and off. The parasitic resistance causes the PVIN voltage to dip during a load transient. If the regulator is operating close to the minimum input voltage, this dip can cause false UVLO fault triggering and a system reset. The best way to solve such issues is to reduce the distance from the input supply to the regulator and use an aluminum or tantalum input capacitor in parallel with the ceramics. The moderate ESR of the electrolytic capacitors helps to damp the input resonant circuit and reduce any voltage overshoots. A capacitance in the range of 20 μ F to 100 μ F is usually sufficient to provide input damping and helps to hold the input voltage steady during large load transients.

An EMI input filter is often used in front of the regulator that, unless carefully designed, can lead to instability as well as some of the effects mentioned above. The user guide *Simple Success with Conducted EMI for DC-DC Converters*, [SNVA489](#), provides helpful suggestions when designing an input filter for any switching regulator.

10 Layout

10.1 Layout Guidelines

PC board layout is an important and critical part of any DC-DC converter design. The performance of any switching converter depends as much upon the layout of the PCB as the component selection. Poor layout disrupts the performance of a switching converter and surrounding circuitry by contributing to EMI, ground bounce, conduction loss in the traces, and thermal problems. Erroneous signals can reach the DC-DC converter, possibly resulting in poor regulation or instability. There are several paths that conduct high slew-rate currents or voltages that can interact with stray inductance or parasitic capacitance to generate noise and EMI or degrade the power-supply performance.

The following guidelines serve to help users to design a PCB with the best power conversion performance, thermal performance, and minimized generation of unwanted EMI.

1. Locate the input capacitors as close as possible to the PVIN and PGND pins, and place the inductor as close as possible to the SW pins and output capacitors. As described further in the [Compact PCB Layout for EMI Reduction](#) section, this placement is to minimize the area of switching current loops and reduce the resistive loss of the high current path. Ideally, use a ground plane on the top layer that connects the PGND pins, the exposed pad of the device, and the return terminals of the input and output capacitors in a small area near pins 10 and 11 of the device. For more details, refer to the board layout detailed in application note *AN-2131 LM21215A Evaluation Board*, [SNVA477](#).
2. Minimize the copper area of the switch node. Route the six SW pins on a single top-layer plane to the inductor terminal using a wide trace to minimize conduction loss. The inductor can be placed on the bottom side of the PCB relative to the LM21215A, but take care to avoid any coupling of the inductor's magnetic field to sensitive feedback or compensation traces.
3. Use a solid ground plane on layer two of the PCB, particularly underneath the LM21215A and power stage components. This plane functions as a noise shield and also as a heat dissipation path.
4. Make input and output power bus connections as wide and short as possible to reduce voltage drops on the input and output of the converter and to improve efficiency. Use copper planes on top to connect the multiple PVIN pins and PGND pins together.
5. Provide enough PCB area for proper heat-sinking. As stated in the [Thermal Design](#) section, use enough copper area to ensure a low $R_{\theta JA}$ commensurate with the maximum load current and ambient temperature. Make the top and bottom PCB layers with two ounce copper thickness and no less than one ounce. Use an array of heat-sinking vias to connect the exposed pad to the ground plane on the bottom PCB layer. If the PCB has multiple copper layers as recommended, connect these thermal vias to the inner layer heat-spreading ground planes.
6. Route the sense trace from the VOUT point of regulation to the feedback resistors away from the SW pins and inductor to avoid contaminating this feedback signal with switching noise. This routing is most important when high resistances are used to set the output voltage. Routing the feedback trace on a different layer than the inductor and SW node trace is recommended such that a ground plane exists between the sense trace and inductor or SW node polygon to provide further cancellation of EMI on the feedback trace.
7. If voltage accuracy at the load is important, ensure that the feedback voltage sense is made directly at the load terminals. Doing so corrects for voltage drops in the PCB planes and traces and provides optimal output voltage setpoint accuracy and load regulation. Place the feedback resistor divider closer to the FB node, rather than close to the load, because the FB node is the input to the error amplifier and is thus noise sensitive. COMP is a also noise-sensitive node and the compensation components must be located as close as possible to the device.
8. Place the AVIN bypass capacitor and the soft-start capacitor close to their respective pins.
9. See [相关文档](#) for additional important guidelines.

Layout Guidelines (continued)

10.1.1 Compact PCB Layout for EMI Reduction

Radiated EMI generated by high di/dt components relates to pulsing currents in switching converters. The larger area covered by the path of a pulsing current, the more electromagnetic emission is generated. The key to reducing radiated EMI is to identify the pulsing current path and minimize the area of that path. The main switching loop of the LM21215A power stage is denoted by #1 in Figure 41. The topological architecture of a buck converter means that particularly high di/dt current flows in loop #1, and it becomes mandatory to reduce the parasitic inductance of this loop by minimizing its effective loop area. For loop #2 however, the di/dt through inductor L_F and capacitor C_{OUT} is naturally limited by the inductor. Keeping the area of loop #2 small is not nearly as important as that of loop #1. Also important are the gate drive loops of the low-side and high-side MOSFETs, which are inherently tight by virtue of the integrated power MOSFETs and gate drivers of the LM21215A

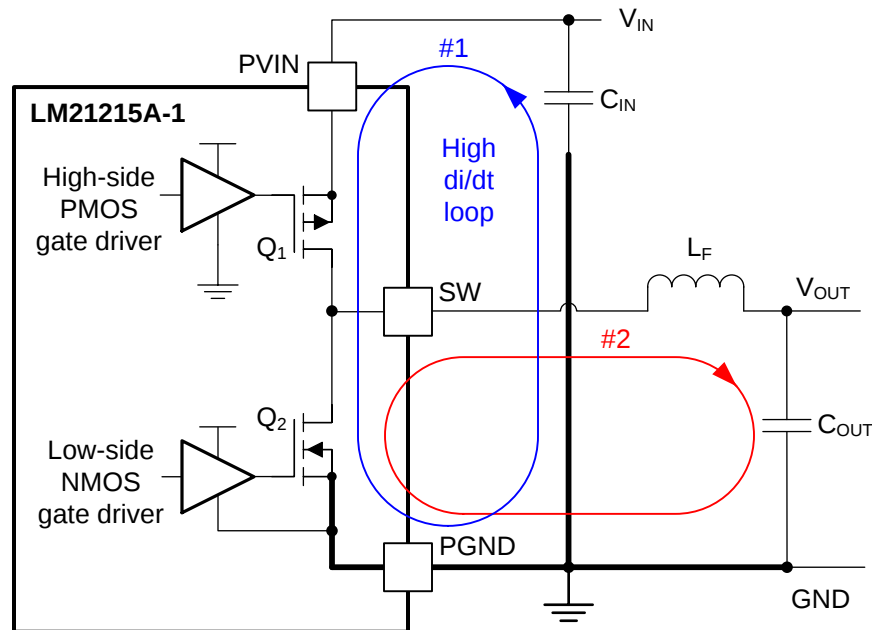


Figure 41. LM21215A Power Stage Circuit Switching Loops

High-frequency ceramic bypass capacitors at the input side provide the primary path for the high di/dt components of the pulsing current. Placing ceramic bypass capacitors as close as possible to the PVIN and PGND pins is the key to EMI reduction. Keep the SW trace connecting to the inductor as short as possible, and just wide enough to carry the load current without excessive heating. Use short, thick traces or copper pours (shapes) for current conduction path to minimize parasitic resistance. Place the output capacitors close to the VOUT side of the inductor and route the return using GND plane copper back to the PGND pins and the exposed pad of the LM21215A.

10.1.2 Thermal Design

As with any power conversion device, the LM21215A dissipates internal power while operating. The effect of this power dissipation is to raise the internal junction temperature of the LM21215A above ambient. The junction temperature (T_J) is a function of the ambient temperature (T_A), the power dissipation and the effective thermal resistance of the device and PCB combination ($R_{\theta JA}$). The maximum operating junction temperature for the LM21215A is 125°C, thus establishing a limit on the maximum device power dissipation and therefore the load current at high ambient temperatures. Equation 20 shows the relationships between these parameters.

$$I_{OUT} = \frac{(T_J - T_A)}{R_{\theta JA}} \cdot \frac{\eta}{(1 - \eta)} \cdot \frac{1}{V_{OUT}} \quad (20)$$

Layout Guidelines (continued)

High ambient temperatures and large values of $R_{\theta JA}$ reduce the maximum available output current. If the junction temperature exceeds 165°C, the LM21215A cycles in and out of thermal shutdown. Thermal shutdown may be a sign of inadequate heat-sinking or excessive power dissipation. Improve PCB heat-sinking by using more thermal vias, a larger board, or more heat-spreading layers within that board.

As stated in application note *Semiconductor and IC Package Thermal Metrics*, [SPRA953](#), the values given in the [Thermal Information](#) table are not always valid for design purposes to estimate the thermal performance of the application. The values reported in the [Thermal Information](#) table are measured under a specific set of conditions that are seldom obtained in an actual application. The effective $R_{\theta JA}$ is a critical parameter and depends on many factors (such as power dissipation, air temperature, PCB area, copper heat-sink area, number of thermal vias under the package, air flow, and adjacent component placement). The LM21215A uses an advanced flip-chip-on-lead (FCOL) package and its exposed pad has a direct electrical and thermal connection to PGND. This pad must be soldered directly to the PCB copper ground plane to provide an effective heat-sink and proper electrical connection. Use the documents listed in [相关文档](#) as a guide for optimized thermal PCB design and estimating $R_{\theta JA}$ for a given application environment.

10.1.3 Ground Plane Design

As mentioned previously, using one of the middle layers as a solid ground plane is recommended. A ground plane offers shielding for sensitive circuits and traces and also provides a quiet reference potential for the control circuitry. Connect the AGND and PGND pins to the ground plane using an array of vias under the exposed pad. The PGND pins are connected to the source of the integrated low-side power MOSFET. Connect these pins directly to the return terminals of the input and output capacitors. The PGND net contains noise at the switching frequency and can bounce because of load current variations. The PGND trace, as well as PVIN and SW traces, must be constrained to one side of the ground plane. The other side of the ground plane contains much less noise and is ideal for sensitive routes.

10.2 Layout Example

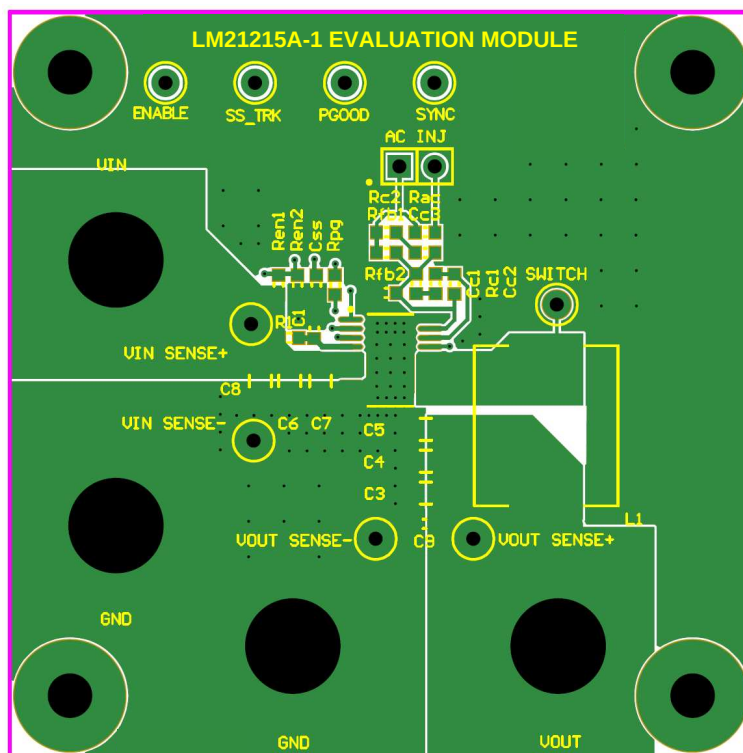


Figure 42. Layout Example Showing Top Layer Copper and Silkscreen

11 器件和文档支持

11.1 器件支持

11.1.1 第三方产品免责声明

TI 发布的与第三方产品或服务有关的信息，不能构成与此类产品或服务或保修的适用性有关的认可，不能构成此类产品或服务单独或与任何 TI 产品或服务一起的表示或认可。

11.1.2 开发支持

有关 LM21215A 快速入门设计工具的信息，请访问 <http://www.ti.com.cn/product/cn/LM21215A/toolssoftware#devtools>。

有关 PowerLab™ 的信息，请访问 <http://www.ti.com.cn/powerlab>。

11.1.2.1 使用 WEBENCH® 工具创建定制设计方案

单击[此处](#)，使用 LM21215A 器件并借助 WEBENCH® 电源设计器创建定制设计方案。

1. 首先输入输入电压 (V_{IN})、输出电压 (V_{OUT}) 和输出电流 (I_{OUT}) 要求。
2. 使用优化器拨盘优化该设计的关键参数，如效率、尺寸和成本。
3. 将生成的设计与德州仪器 (TI) 的其他可行的解决方案进行比较。

WEBENCH 电源设计器可提供定制原理图以及罗列实时价格和组件供货情况的物料清单。

在多数情况下，可执行以下操作：

- 运行电气仿真，观察重要波形以及电路性能
- 运行热性能仿真，了解电路板热性能
- 将定制原理图和布局方案以常用 CAD 格式导出
- 打印设计方案的 PDF 报告并与同事共享

有关 WEBENCH 工具的详细信息，请访问 www.ti.com.cn/WBENCH。

11.2 文档支持

11.2.1 相关文档

- 《AN-2131 LM21215A 评估板》，[SNVA477](#)
- 《AN-2130 LM21215 评估板》，[SNVA476](#)
- 《AN-2107 LM21212-1 评估板》，[SNVA467](#)
- 《AN-2140 LM21212-2 评估板》，[SNVA480](#)
- AN-2162: 《轻松抑制 DC-DC 转换器中的传导性 EMI》，[SNVA489](#)
- 《用于负载点稳压器且具有可调节启动电流的 6/4 位 VID 可编程电流 DAC》，[SNVS822](#)
- 《AN-1149 开关电源布局指南》，[SNVA021](#)
- 《AN-1229 Simple Switcher PCB 布局指南》，[SNVA054](#)
- 《构建电源 - 布局注意事项》，[SLUP230](#)
- 《使用 LM4360x 与 LM4600x 简化低辐射 EMI 布局》，[SNVA721](#)
- 《AN-2020 热设计：学会洞察先机，不做事后诸葛》，[SNVA419](#)
- 《确保外露焊盘封装的最佳热阻性的 AN-1520 电路板布局指南》，[SNVA183](#)
- 《SPRA953B 半导体和 IC 封装热指标》，[SPRA953](#)
- 《使用 LM43603 和 LM43602 简化 SNVA719 热设计》，[SNVA719](#)
- 《SLMA002 PowerPAD™ 热增强型封装》，[SLMA002](#)
- 《SLMA004 PowerPAD 速成》，[SLMA004](#)
- 《SBVA025 使用新的热指标》，[SBVA025](#)

11.3 社区资源

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.4 商标

PowerPAD, E2E are trademarks of Texas Instruments.
WEBENCH is a registered trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

11.5 静电放电警告



这些装置包含有限的内置 ESD 保护。存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

11.6 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 机械、封装和可订购信息

以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。数据如有变更，恕不另行通知，且不会对此文档进行修订。如需获取此数据表的浏览器版本，请查阅左侧的导航栏。

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM21215AMH-1/NOPB	Active	Production	HTSSOP (PWP) 20	73 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM21215 AMH-1
LM21215AMH-1/NOPB.A	Active	Production	HTSSOP (PWP) 20	73 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM21215 AMH-1
LM21215AMH-1/NOPB.B	Active	Production	HTSSOP (PWP) 20	73 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM21215 AMH-1
LM21215AMHE-1/NOPB	Active	Production	HTSSOP (PWP) 20	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM21215 AMH-1
LM21215AMHE-1/NOPB.A	Active	Production	HTSSOP (PWP) 20	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM21215 AMH-1
LM21215AMHE-1/NOPB.B	Active	Production	HTSSOP (PWP) 20	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM21215 AMH-1
LM21215AMHX-1/NOPB	Active	Production	HTSSOP (PWP) 20	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM21215 AMH-1
LM21215AMHX-1/NOPB.A	Active	Production	HTSSOP (PWP) 20	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM21215 AMH-1
LM21215AMHX-1/NOPB.B	Active	Production	HTSSOP (PWP) 20	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM21215 AMH-1
LM21215AMHX1NOPBG4.A	Active	Production	HTSSOP (PWP) 20	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM21215 AMH-1
LM21215AMHX1NOPBG4.B	Active	Production	HTSSOP (PWP) 20	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LM21215 AMH-1

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

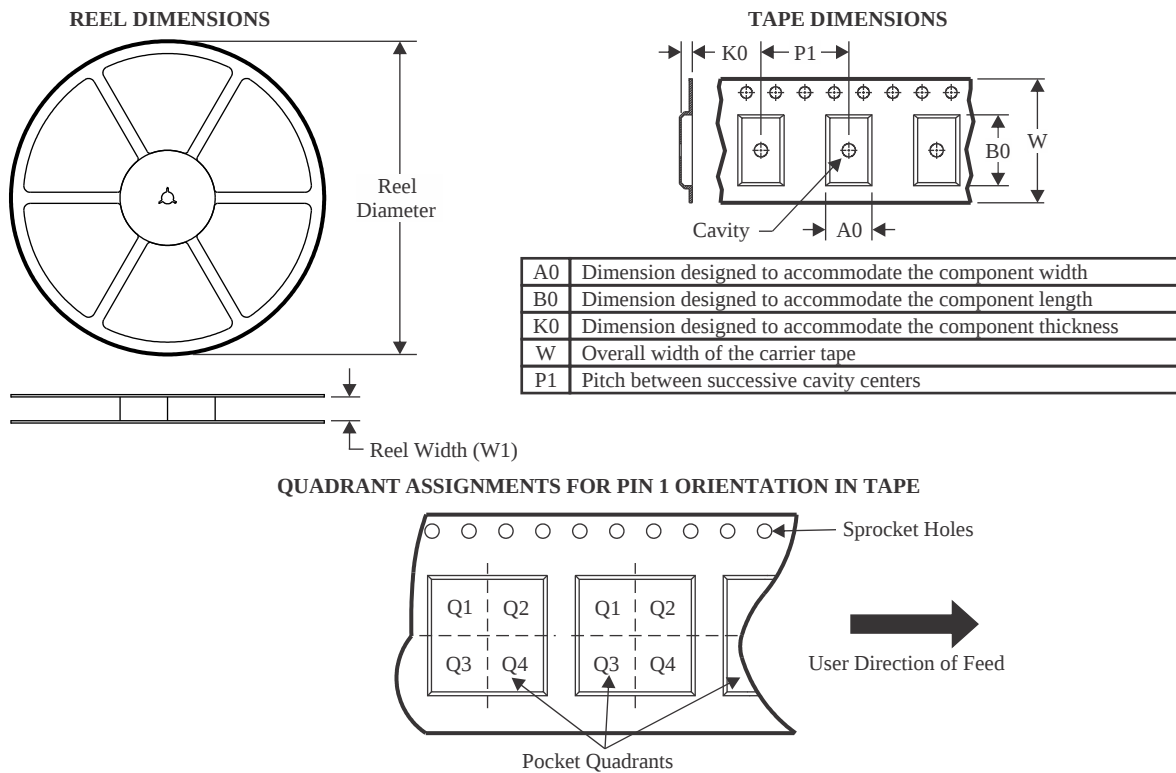
⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

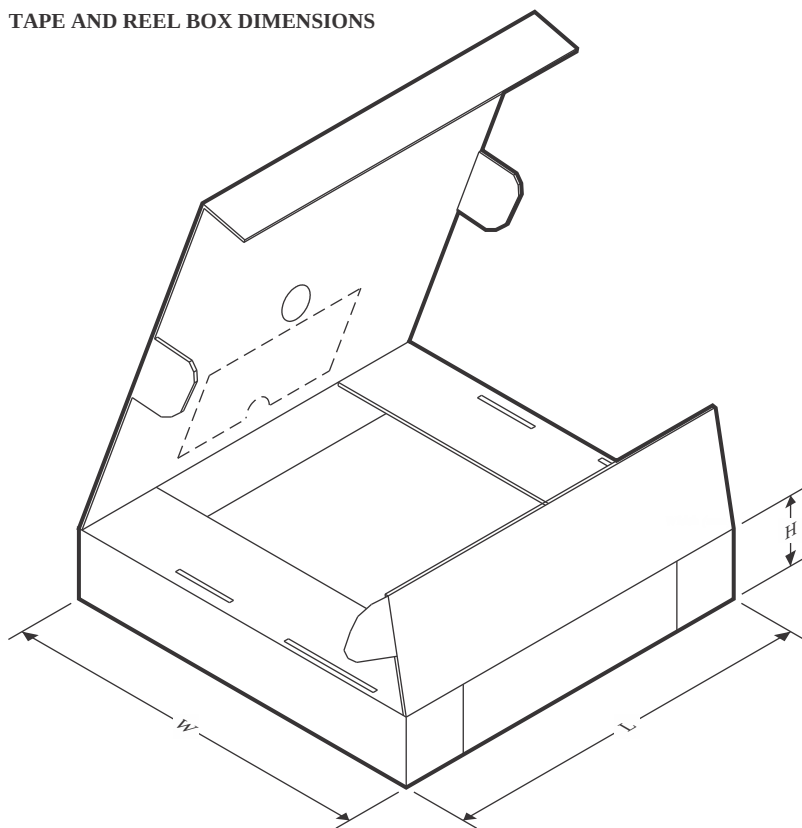
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM21215AMHE-1/NOPB	HTSSOP	PWP	20	250	178.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
LM21215AMHX-1/NOPB	HTSSOP	PWP	20	2500	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

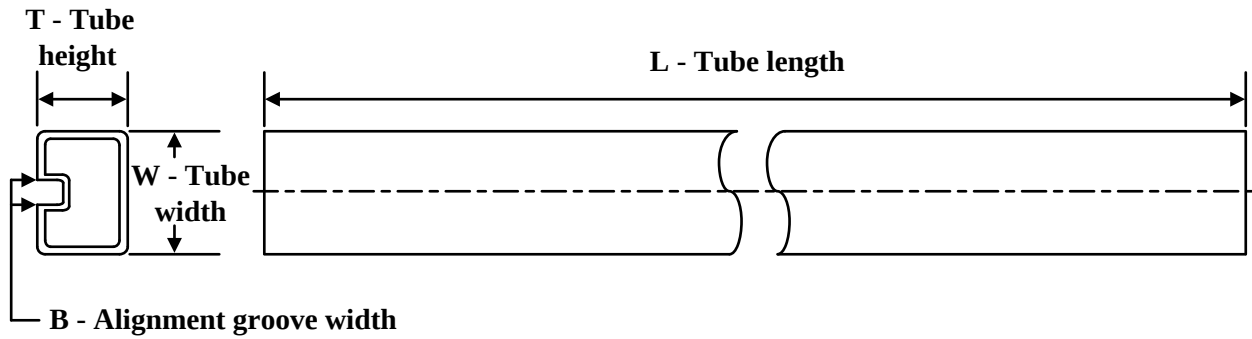
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM21215AMHE-1/NOPB	HTSSOP	PWP	20	250	210.0	185.0	35.0
LM21215AMHX-1/NOPB	HTSSOP	PWP	20	2500	367.0	367.0	35.0

TUBE

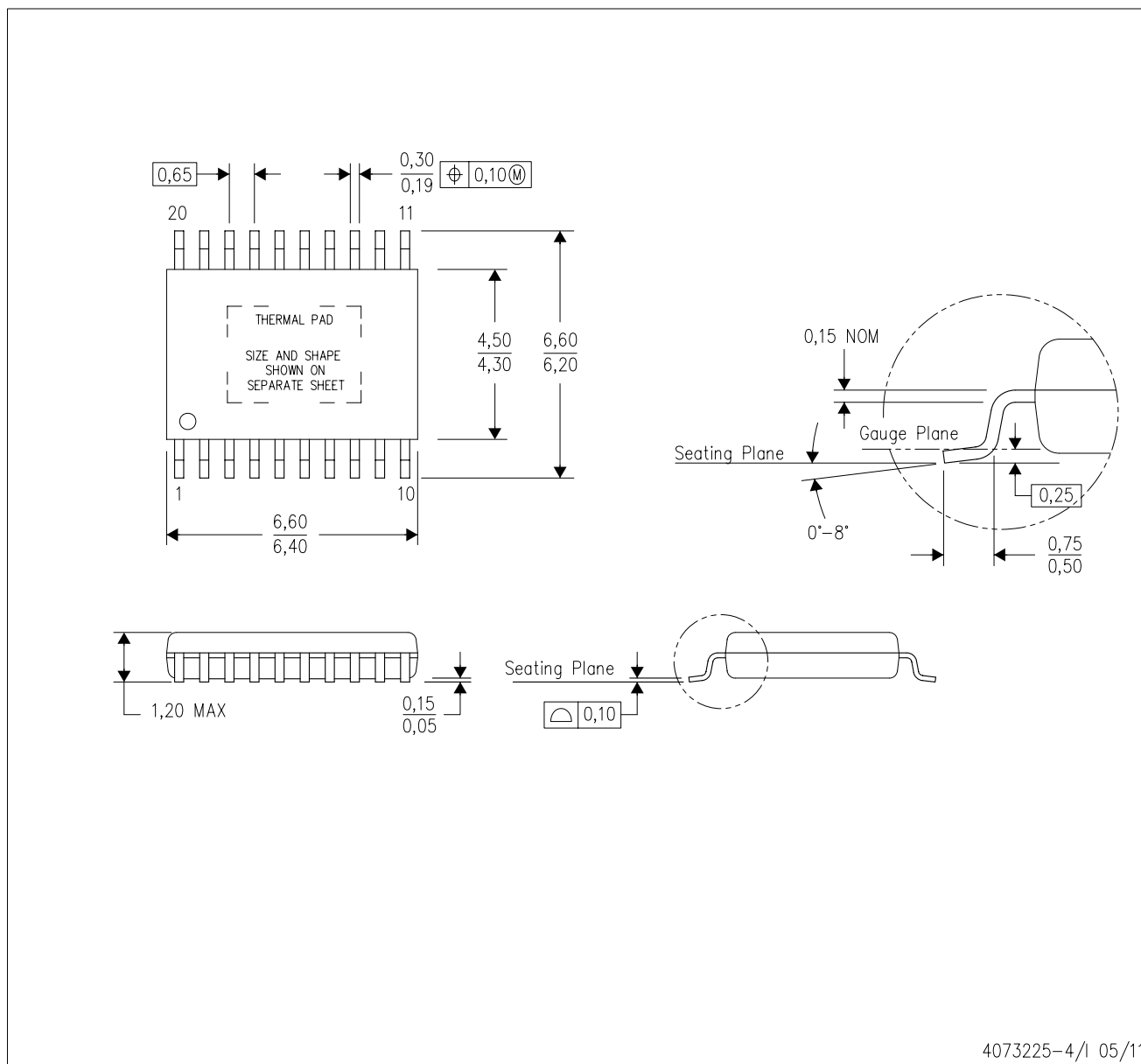


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
LM21215AMH-1/NOPB	PWP	HTSSOP	20	73	495	8	2514.6	4.06
LM21215AMH-1/NOPB.A	PWP	HTSSOP	20	73	495	8	2514.6	4.06
LM21215AMH-1/NOPB.B	PWP	HTSSOP	20	73	495	8	2514.6	4.06

PWP (R-PDSO-G20)

PowerPAD™ PLASTIC SMALL OUTLINE

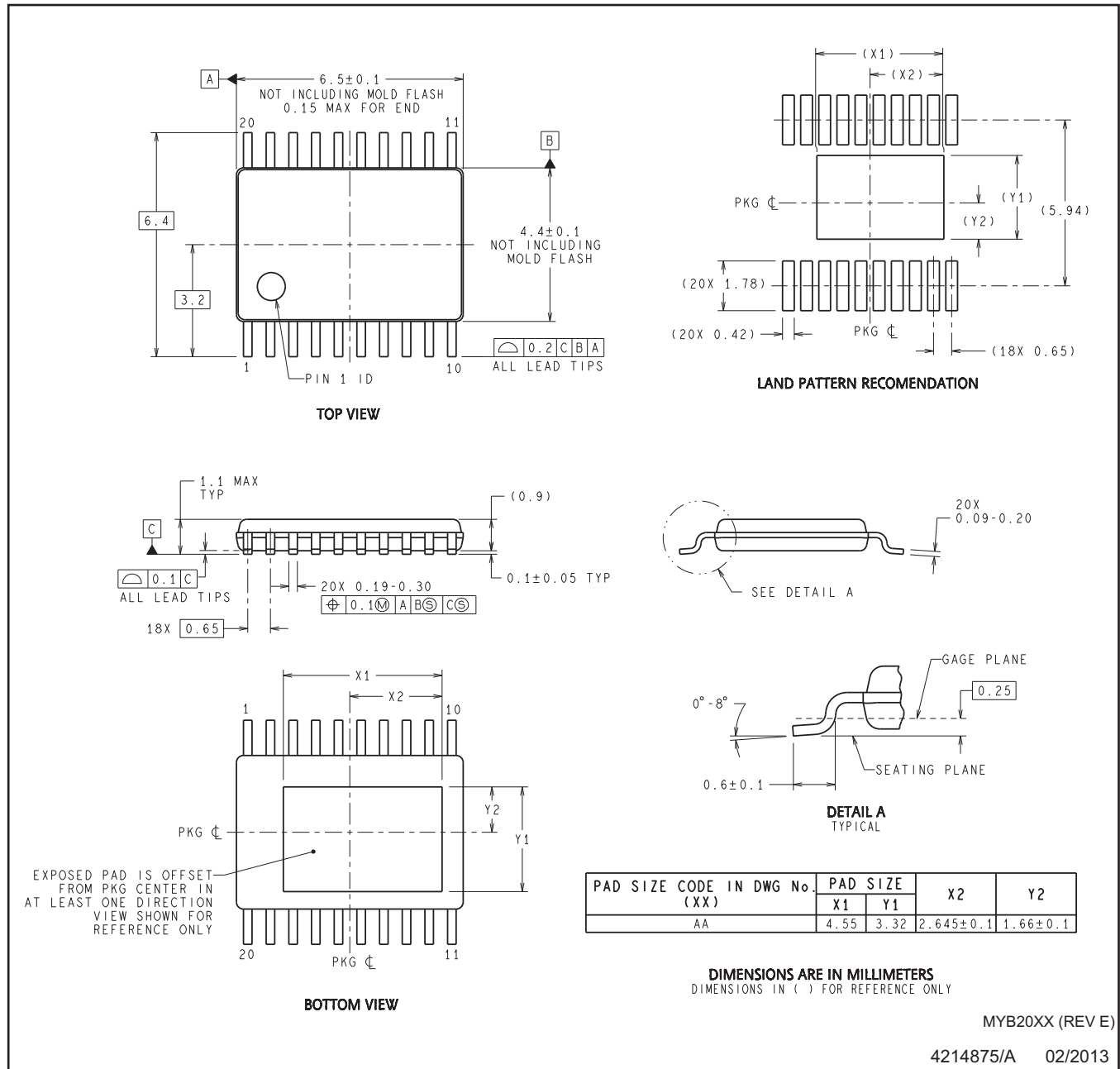


4073225-4/1 05/11

- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Body dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.15 per side.
 - This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <<http://www.ti.com>>.
 - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
 - Falls within JEDEC MO-153

PowerPAD is a trademark of Texas Instruments.

PWP0020AA



- NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.
C. Reference JEDEC Registration MO-153, Variation ACT.

重要通知和免责声明

TI“按原样”提供技术和可靠性数据（包括数据表）、设计资源（包括参考设计）、应用或其他设计建议、网络工具、安全信息和其他资源，不保证没有瑕疵且不做任何明示或暗示的担保，包括但不限于对适销性、与某特定用途的适用性或不侵犯任何第三方知识产权的暗示担保。

这些资源可供使用 TI 产品进行设计的熟练开发人员使用。您将自行承担以下全部责任：(1) 针对您的应用选择合适的 TI 产品，(2) 设计、验证并测试您的应用，(3) 确保您的应用满足相应标准以及任何其他安全、安保法规或其他要求。

这些资源如有变更，恕不另行通知。TI 授权您仅可将这些资源用于研发本资源所述的 TI 产品的相关应用。严禁以其他方式对这些资源进行复制或展示。您无权使用任何其他 TI 知识产权或任何第三方知识产权。对于因您对这些资源的使用而对 TI 及其代表造成的任何索赔、损害、成本、损失和债务，您将全额赔偿，TI 对此概不负责。

TI 提供的产品受 [TI 销售条款](#)、[TI 通用质量指南](#) 或 [ti.com](#) 上其他适用条款或 TI 产品随附的其他适用条款的约束。TI 提供这些资源并不会扩展或以其他方式更改 TI 针对 TI 产品发布的适用的担保或担保免责声明。除非德州仪器 (TI) 明确将某产品指定为定制产品或客户特定产品，否则其产品均为按确定价格收入目录的标准通用器件。

TI 反对并拒绝您可能提出的任何其他或不同的条款。

版权所有 © 2025，德州仪器 (TI) 公司

最后更新日期：2025 年 10 月